



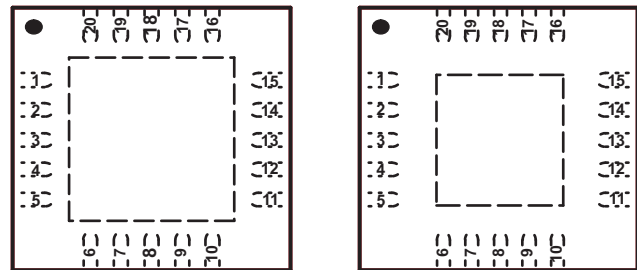
## 80-mW DIRECTPATH™ STEREO HEADPHONE DRIVER

### FEATURES

- **Space Saving Packages**
  - 20-Pin, 4 mm × 4 mm Thin QFN
  - TPA4411 – Thermally Optimized PowerPAD™ Package
  - TPA4411M – Thermally Enhanced PowerPAD™ Package
  - 16-Ball, 2.18 mm × 2.18 mm WCSP
- **Ground-Referenced Outputs Eliminate DC-Bias Voltages on Headphone Ground Pin**
  - No Output DC-Blocking Capacitors
    - Reduced Board Area
    - Reduced Component Cost
    - Improved THD+N Performance
    - No Degradation of Low-Frequency Response Due to Output Capacitors
- **Wide Power Supply Range: 1.8 V to 4.5 V**
- **80-mW/Ch Output Power into 16-Ω at 4.5 V**
- **Independent Right and Left Channel Shutdown Control**
- **Short-Circuit and Thermal Protection**
- **Pop Reduction Circuitry**

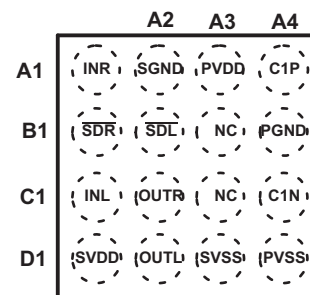
### APPLICATIONS

- **Notebook Computers**
- **CD / MP3 Players**
- **Smart Phones**
- **Cellular Phones**
- **PDA's**



TPA4411RTJ

TPA4411MRTJ



TPA4411YZH

### DESCRIPTION

The TPA4411 and TPA4411M are stereo headphone drivers designed to allow the removal of the output DC-blocking capacitors for reduced component count and cost. The TPA4411 and TPA4411M are ideal for small portable electronics where size and cost are critical design parameters.

The TPA4411 and TPA4411M are capable of driving 80 mW into a 16-Ω load at 4.5 V. Both TPA4411 and TPA4411M have a fixed gain of  $-1.5$  V/V and headphone outputs that have  $\pm 8$ -kV IEC ESD protection. The TPA4411 and TPA4411M have independent shutdown control for the right and left audio channels.

The TPA4411 is available in a 2.18 mm × 2.18 mm WCSP and 4 mm × 4 mm Thin QFN packages. The TPA4411M is available in a 4 mm × 4 mm Thin QFN package. The TPA4411RTJ package is a thermally optimized PowerPAD™ package allowing the maximum amount of thermal dissipation and the TPA4411MRTJ is a thermally enhanced PowerPAD package designed to match competitive package footprints.



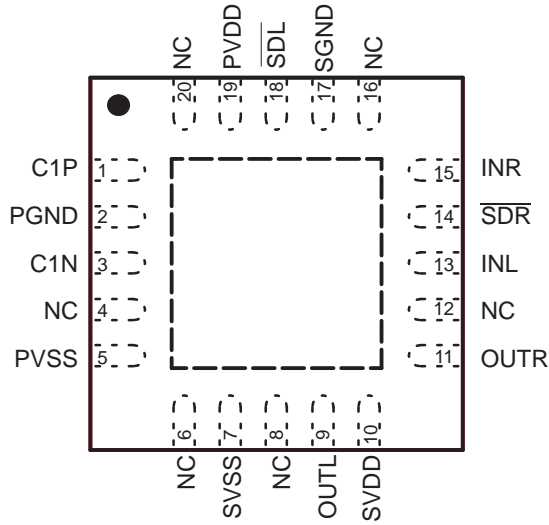
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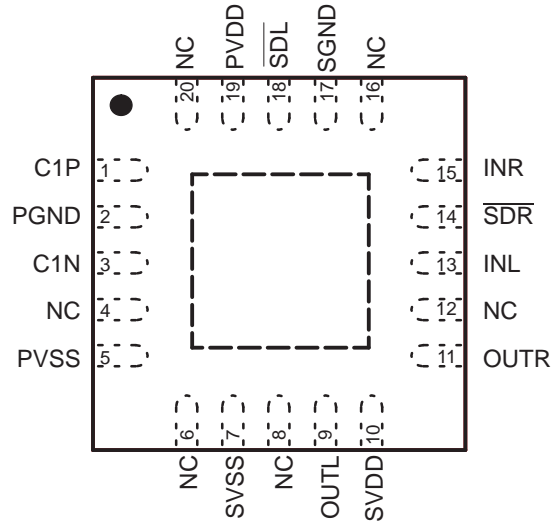
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**RTJ (QFN) PACKAGE  
(TOP VIEW)**



**TPA4411RTJ**

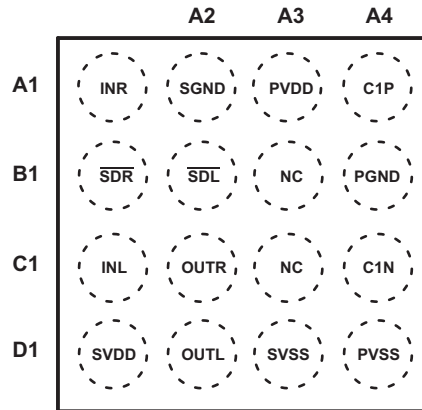
NC – No internal connection



**TPA4411MRTJ**

NC – No internal connection

**YZH (WCSP) PACKAGE  
(TOP VIEW)**



**TPA4411YZH**

NC - No internal connection

**TERMINAL FUNCTIONS**

TERMINAL			I/O	DESCRIPTION
NAME	QFN	WCSP		
C1P	1	A4	I/O	Charge pump flying capacitor positive terminal
PGND	2	B4	I	Power ground, connect to ground.
C1N	3	C4	I/O	Charge pump flying capacitor negative terminal
NC	4, 6, 8, 12, 16, 20	B3, C3		No connection
PVSS	5	D4	O	Output from charge pump.
SVSS	7	D3	I	Amplifier negative supply, connect to PVSS via star connection.
OUTL	9	D2	O	Left audio channel output signal
SVDD	10	D1	I	Amplifier positive supply, connect to PVDD via star connection.
OUTR	11	C2	O	Right audio channel output signal
INL	13	C1	I	Left audio channel input signal
$\overline{\text{SDR}}$	14	B1	I	Right channel shutdown, active low logic.
INR	15	A1	I	Right audio channel input signal
SGND	17	A2	I	Signal ground, connect to ground.
$\overline{\text{SDL}}$	18	B2	I	Left channel shutdown, active low logic.
PVDD	19	A3	I	Supply voltage, connect to positive supply.
Exposed Pad		-		Exposed pad must be soldered to a floating plane. Do NOT connect to power or ground.

**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

over operating free-air temperature range,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

		VALUE / UNIT
	Supply voltage, AVDD, PVDD	-0.3 V to 5.5 V
$V_I$	Input voltage	-0.3 V to $V_{DD} + 0.3$ V
	Output Continuous total power dissipation	See Dissipation Rating Table
$T_A$	Operating free-air temperature range	-40°C to 85°C
$T_J$	Operating junction temperature range	-40°C to 150°C
$T_{\text{stg}}$	Storage temperature range	-65°C to 150°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### DISSIPATION RATINGS TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR <sup>(1)</sup>	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
RTJ (TPA4411)	5200 mW	41.6 mW/°C	3120 mW	2700 mW
RTJ (TPA4411M)	3450 mW	34.5 mW/°C	1898 mW	1380 mW
YZH	1200 mW	9.21 mW/°C	690 mW	600 mW

(1) Derating factor measured with High K board.

### AVAILABLE OPTIONS

$T_A$	PACKAGED DEVICES <sup>(1)</sup>	PART NUMBER	SYMBOL
-40°C to 85°C	20-pin, 4 mm × 4 mm QFN	TPA4411RTJ <sup>(2)</sup>	AKQ
	20-pin, 4 mm × 4 mm QFN	TPA4411MRTJ <sup>(2)</sup>	BPB
	16-ball, 2.18 mm × 2.18 mm WSCP	TPA4411YZH	AKT

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com).  
 (2) The RTJ package is only available taped and reeled. To order, add the suffix "R" to the end of the part number for a reel of 3000, or add the suffix "T" to the end of the part number for a reel of 250 (e.g., TPA4411RTJR).

### RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
Supply voltage, AVDD, PVDD			1.8	4.5 <sup>(1)</sup>	V
$V_{IH}$	High-level input voltage	$\overline{SDL}$ , $\overline{SDR}$	1.5		V
$V_{IL}$	Low-level input voltage	$\overline{SDL}$ , $\overline{SDR}$		0.5	V
$T_A$	Operating free-air temperature		-40	85	°C

(1) Device can shut down for  $V_{DD} > 4.5$  V to prevent damage to the device.

### ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$  (unless otherwise noted)

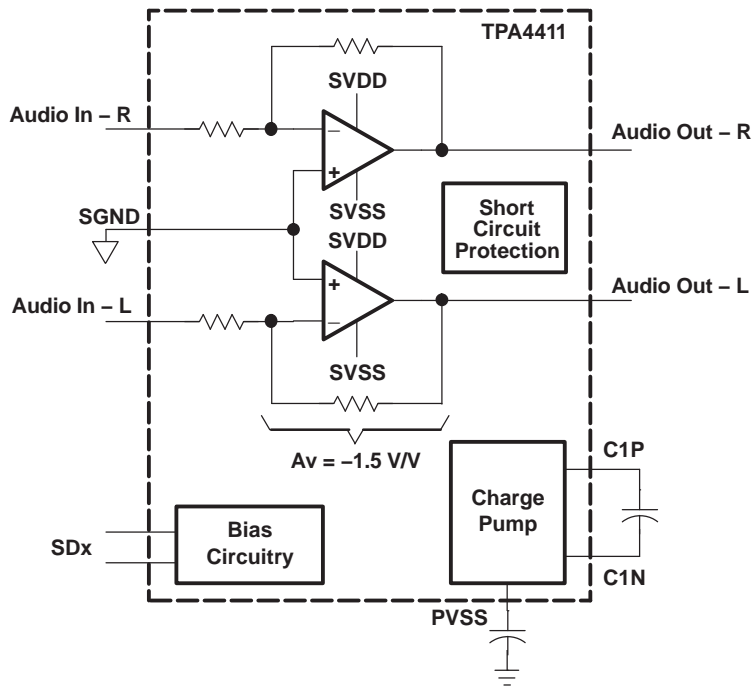
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VOS	Output offset voltage	$V_{DD} = 1.8$ V to 4.5 V, Inputs grounded			8	mV
PSRR	Power Supply Rejection Ratio	$V_{DD} = 1.8$ V to 4.5 V	-69	-80		dB
$V_{OH}$	High-level output voltage	$V_{DD} = 3$ V, $R_L = 16 \Omega$	2.2			V
$V_{OL}$	Low-level output voltage	$V_{DD} = 3$ V, $R_L = 16 \Omega$			-1.1	V
$I_{IH}$	High-level input current ( $\overline{SDL}$ , $\overline{SDR}$ )	$V_{DD} = 4.5$ V, $V_I = V_{DD}$			1	$\mu\text{A}$
$I_{IL}$	Low-level input current ( $\overline{SDL}$ , $\overline{SDR}$ )	$V_{DD} = 4.5$ V, $V_I = 0$ V			1	$\mu\text{A}$
$I_{DD}$	Supply Current	$V_{DD} = 1.8$ V, No load, $\overline{SDL} = \overline{SDR} = V_{DD}$		5.3	6.5	mA
		$V_{DD} = 3$ V, No load, $\overline{SDL} = \overline{SDR} = V_{DD}$		6.5	8.0	
		$V_{DD} = 4.5$ V, No load, $\overline{SDL} = \overline{SDR} = V_{DD}$		8.0	10.0	
		Shutdown mode, $V_{DD} = 1.8$ V to 4.5 V				1

## OPERATING CHARACTERISTICS

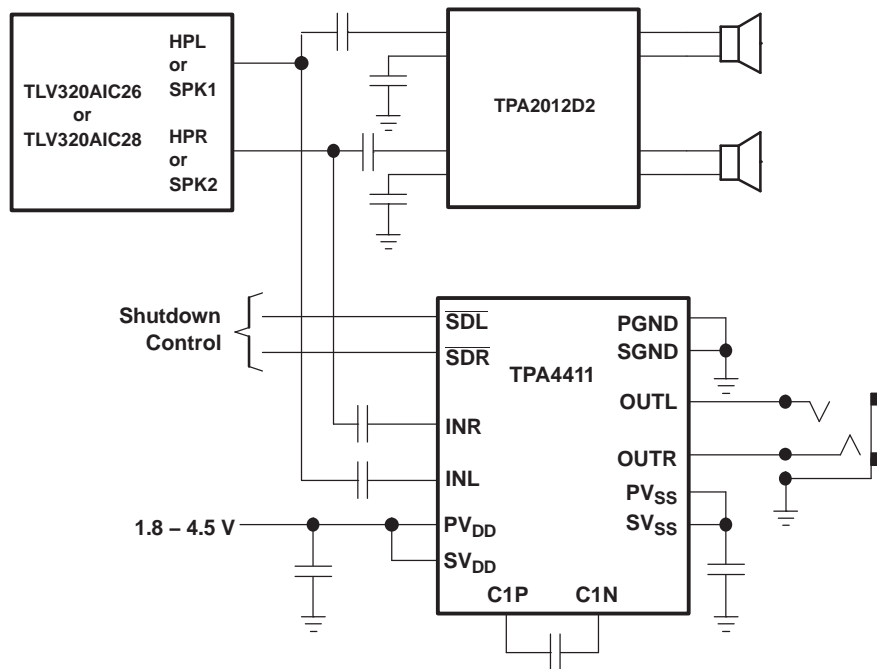
 $V_{DD} = 3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 16\ \Omega$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$P_O$	Output power (Outputs In Phase)	THD = 1%, $V_{DD} = 3\text{ V}$ , $f = 1\text{ kHz}$		50		mW
		THD = 1%, $V_{DD} = 4.5\text{ V}$ , $f = 1\text{ kHz}$		100		
		THD = 1%, $V_{DD} = 3\text{ V}$ , $f = 1\text{ kHz}$ , $R_L = 32\ \Omega$		50		
THD+N	Total harmonic distortion plus noise	$P_O = 25\text{ mW}$ , $f = 1\text{ kHz}$		0.054%		
		$P_O = 25\text{ mW}$ , $f = 20\text{ kHz}$		0.010%		
	Crosstalk	$P_O = 20\text{ mW}$ , $f = 1\text{ kHz}$		-83		dB
$k_{SVR}$	Supply ripple rejection ratio	200-mV <sub>pp</sub> ripple, $f = 217\text{ Hz}$		-82.5		dB
		200-mV <sub>pp</sub> ripple, $f = 1\text{ kHz}$		-70.4		
		200-mV <sub>pp</sub> ripple, $f = 20\text{ kHz}$		-45.1		
$A_v$	Closed-loop voltage gain		-1.45	-1.5	-1.55	V/V
$\Delta A_v$	Gain matching			1%		
	Slew rate			2.2		V/ $\mu\text{s}$
	Maximum capacitive load			400		pF
$V_n$	Noise output voltage			10		$\mu\text{V}_{RMS}$
	Electrostatic discharge, IEC	OUTR, OUTL		$\pm 8$		kV
$f_{osc}$	Charge pump switching frequency		280	320	420	kHz
	Start-up time from shutdown			450		$\mu\text{s}$
	Input impedance		12	15	18	k $\Omega$
SNR	Signal-to-noise ratio	$P_O = 40\text{ mW}$ (THD+N = 0.1%)		98		dB
	Thermal shutdown	Threshold	150		170	$^\circ\text{C}$
		Hysteresis		15		$^\circ\text{C}$

Functional Block Diagram



APPLICATION CIRCUIT

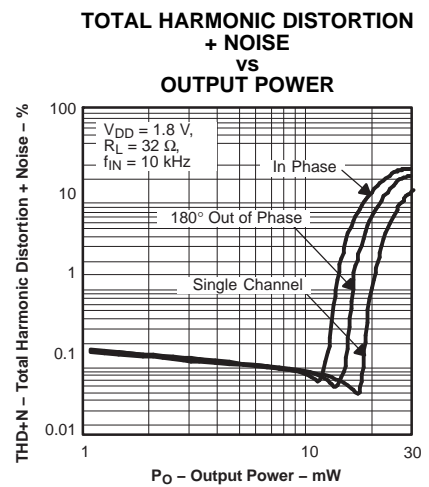
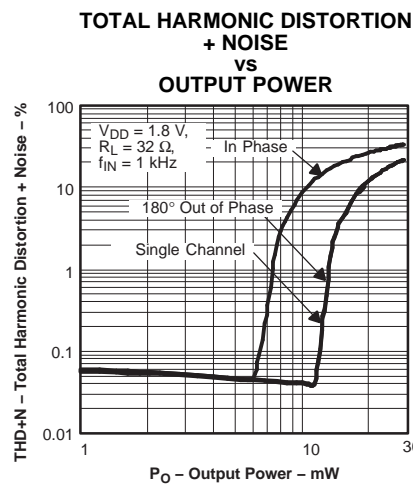
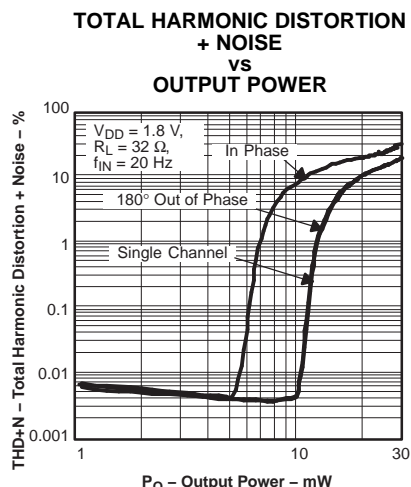
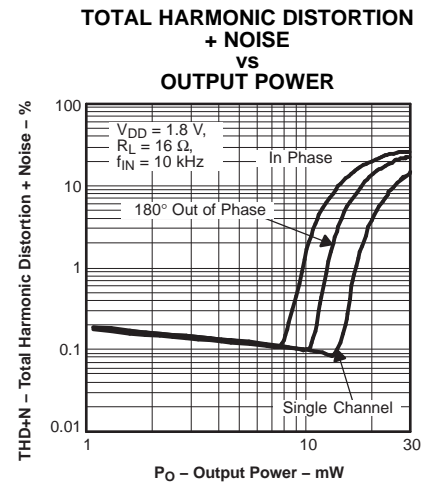
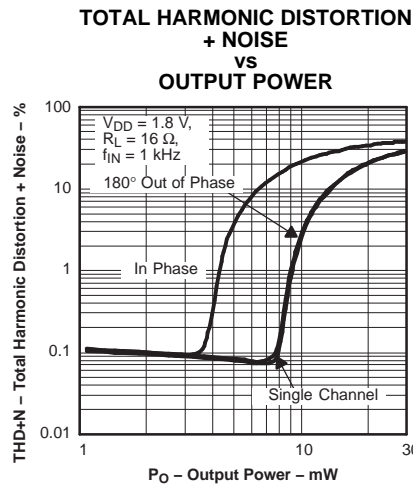
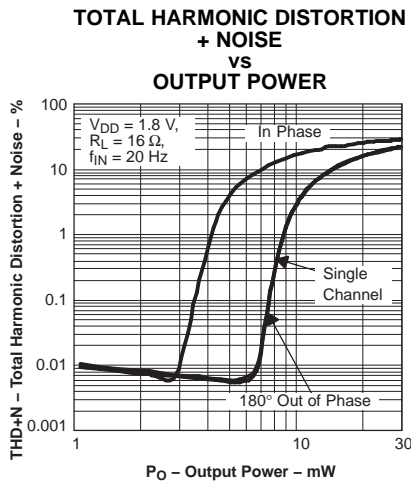


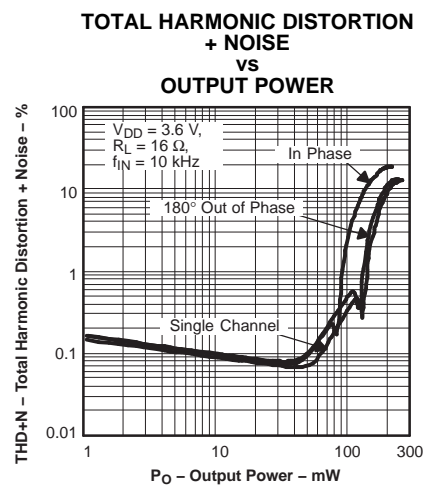
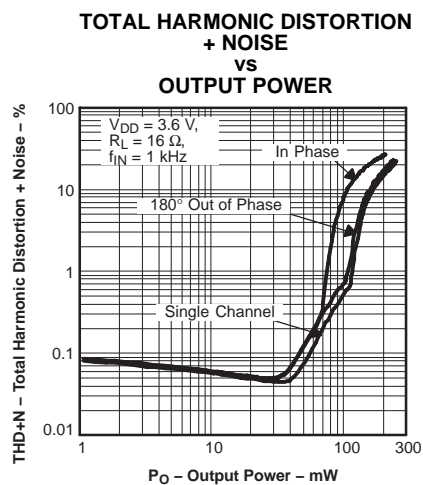
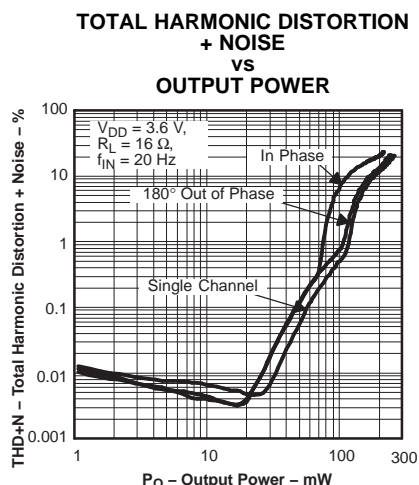
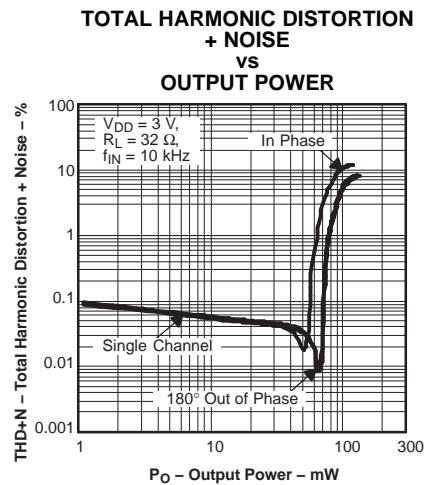
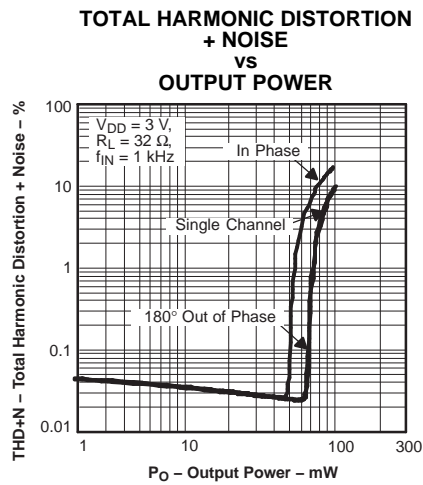
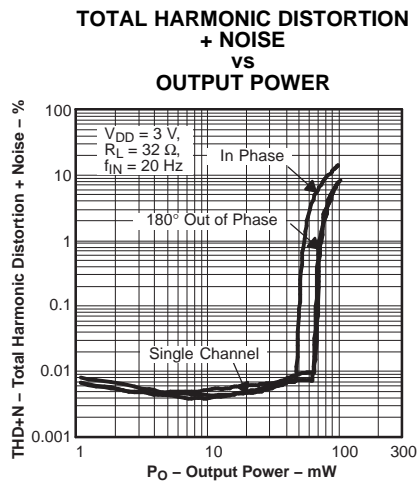
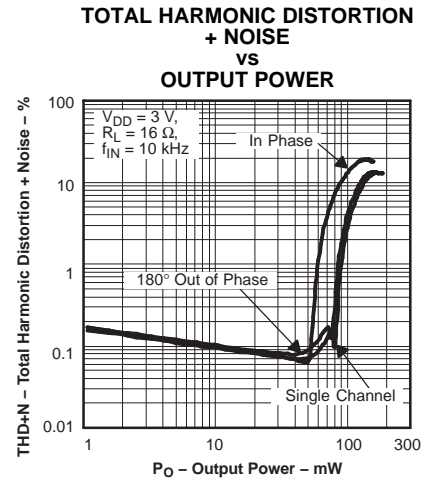
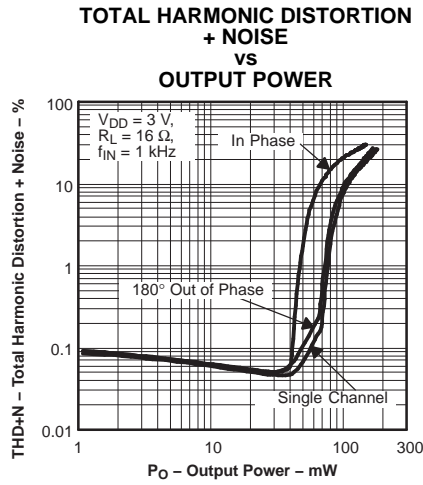
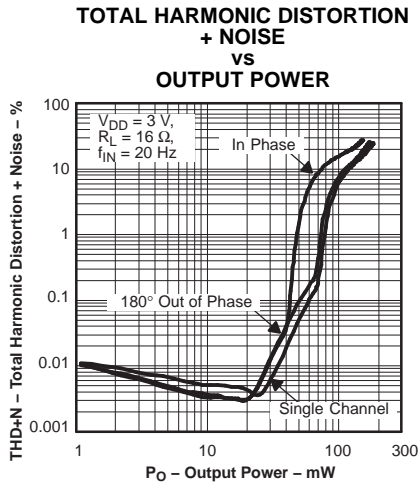
**TYPICAL CHARACTERISTICS**

$C_{(PUMP)} = C_{(PVSS)} = 2.2 \mu\text{F}$ ,  $C_{IN} = 1 \mu\text{F}$  (unless otherwise noted)

**Table of Graphs**

		FIGURE
Total harmonic distortion + noise	vs Output power	1–24
Total harmonic distortion + noise	vs Frequency	25–32
Supply voltage rejection ratio	vs Frequency	33, 34
Power dissipation	vs Output power	35–42
Crosstalk	vs Frequency	43–46
Output power	vs Supply voltage	47–50
Quiescent supply current	vs Supply voltage	51
Output power	vs Load resistance	5–60
Output spectrum		61
Gain and phase	vs Frequency	62, 63







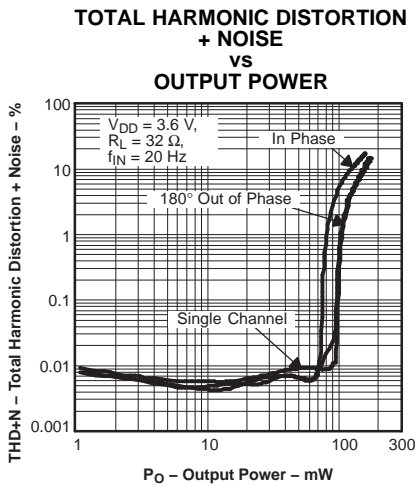


Figure 16.

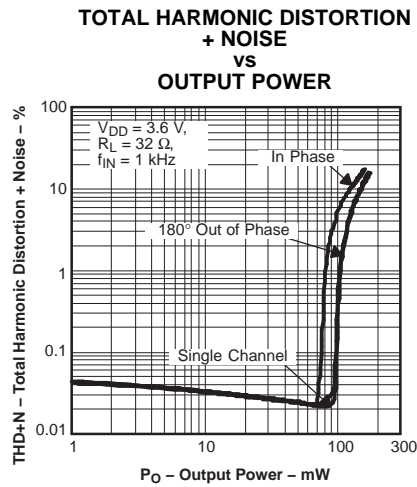


Figure 17.

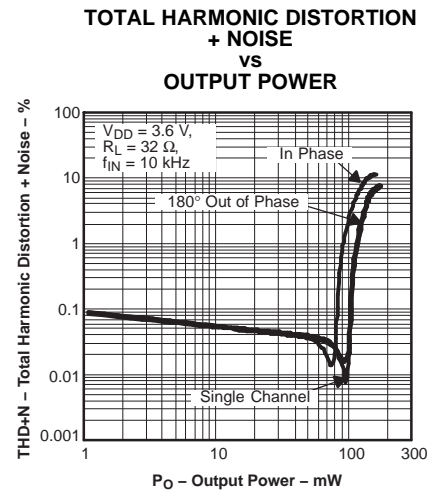


Figure 18.

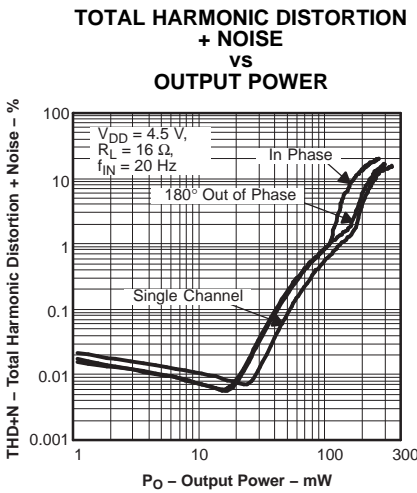


Figure 19.

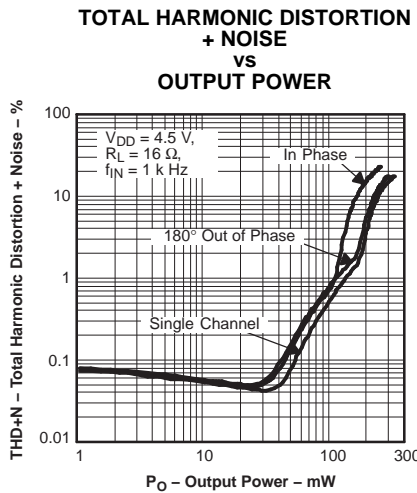


Figure 20.

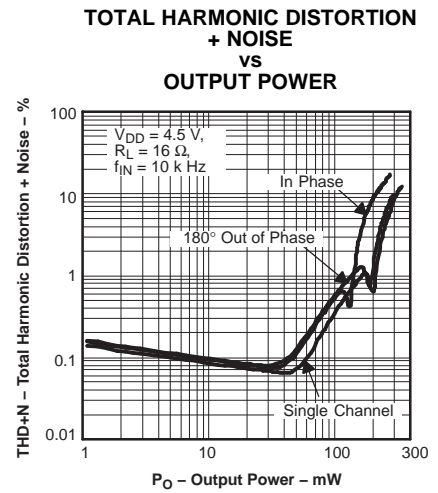


Figure 21.

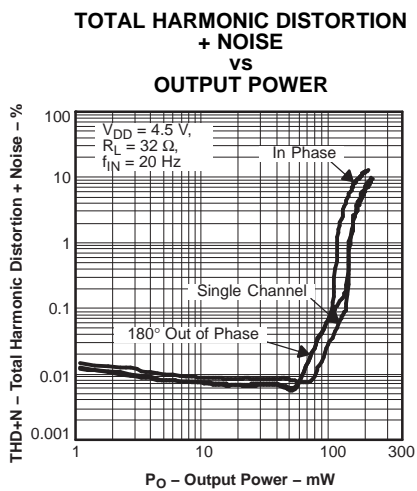


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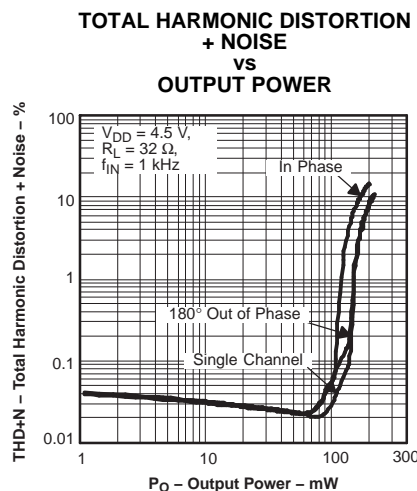


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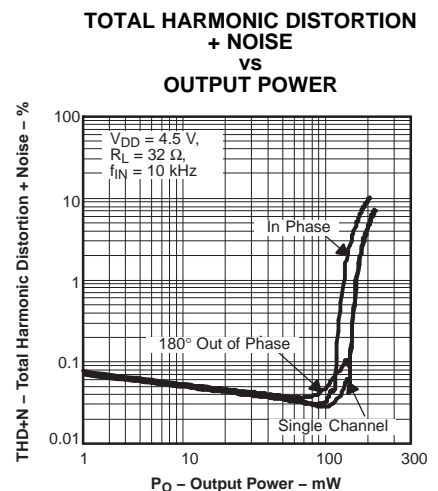


Figure 24.

**TOTAL HARMONIC DISTORTION + NOISE VS FREQUENCY**

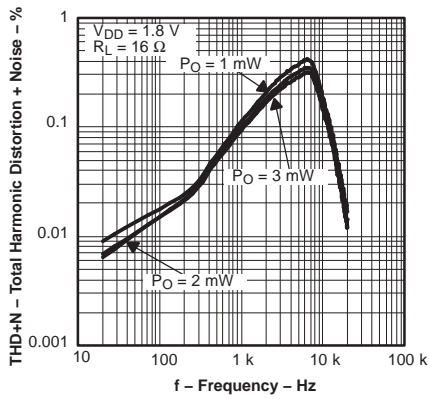


Figure 25.

**TOTAL HARMONIC DISTORTION + NOISE VS FREQUENCY**

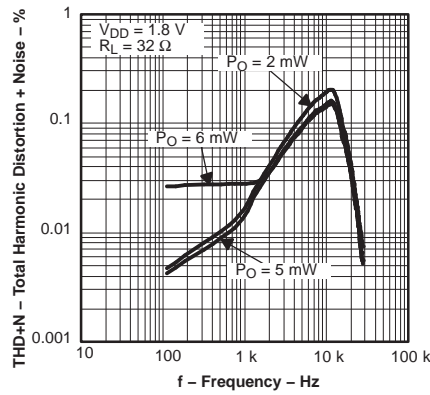


Figure 26.

**TOTAL HARMONIC DISTORTION + NOISE VS FREQUENCY**

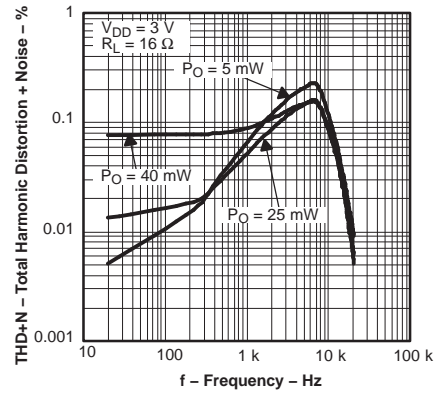


Figure 27.

**TOTAL HARMONIC DISTORTION + NOISE VS FREQUENCY**

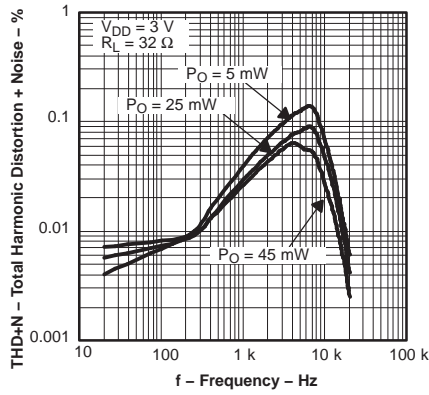


Figure 28.

**TOTAL HARMONIC DISTORTION + NOISE VS FREQUENCY**

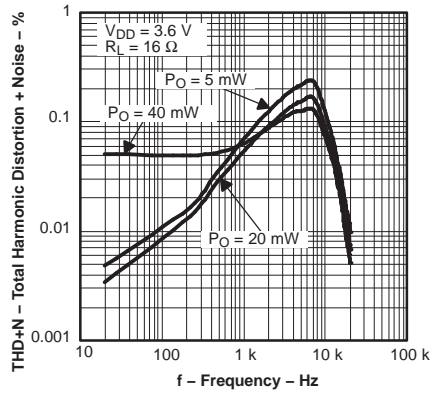


Figure 29.

**TOTAL HARMONIC DISTORTION + NOISE VS FREQUENCY**

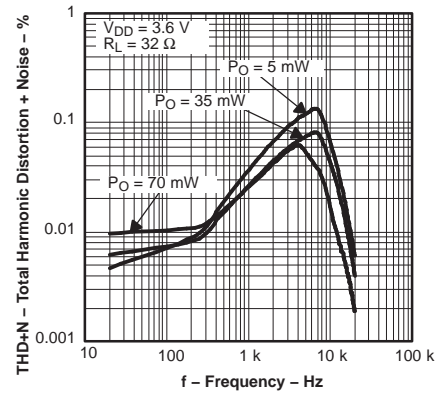


Figure 30.

**TOTAL HARMONIC DISTORTION + NOISE VS FREQUENCY**

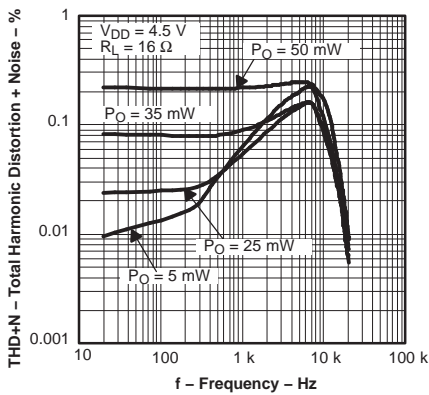


Figure 31.

**TOTAL HARMONIC DISTORTION + NOISE VS FREQUENCY**

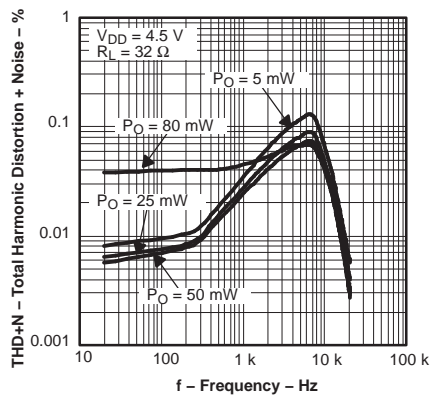


Figure 32.

**SUPPLY VOLTAGE REJECTION RATIO VS FREQUENCY**

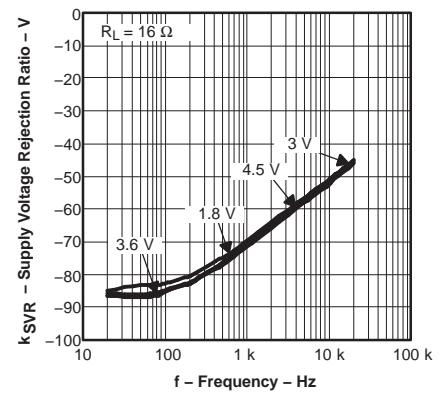


Figure 33.

**SUPPLY VOLTAGE REJECTION RATIO VS FREQUENCY**

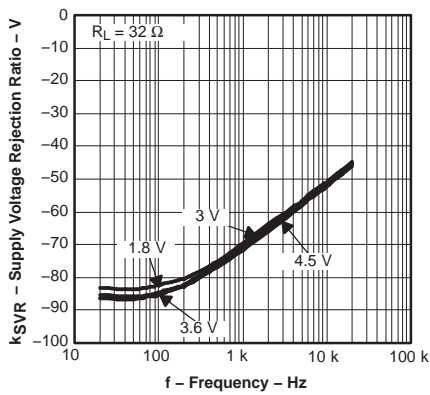


Figure 34.

**POWER DISSIPATION VS OUTPUT POWER**

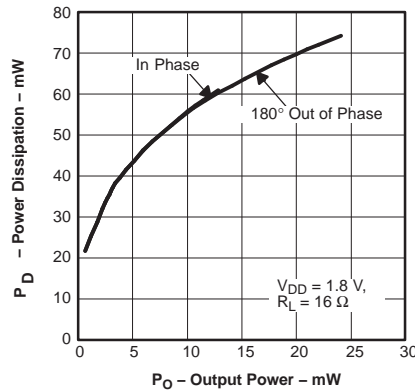


Figure 35.

**POWER DISSIPATION VS OUTPUT POWER**

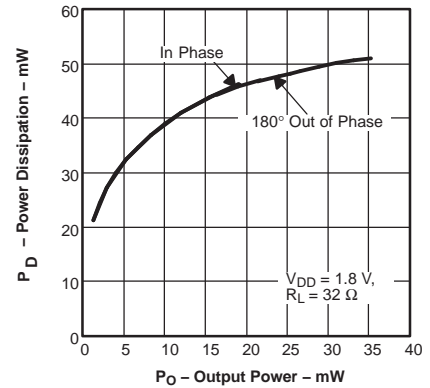


Figure 36.

**POWER DISSIPATION VS OUTPUT POWER**

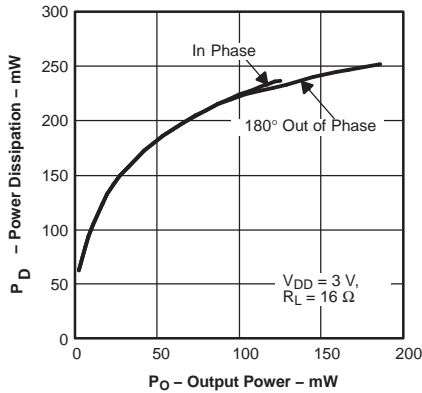


Figure 37.

**POWER DISSIPATION VS OUTPUT POWER**

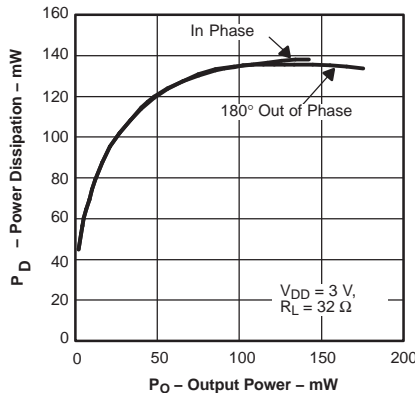


Figure 38.

**POWER DISSIPATION VS OUTPUT POWER**

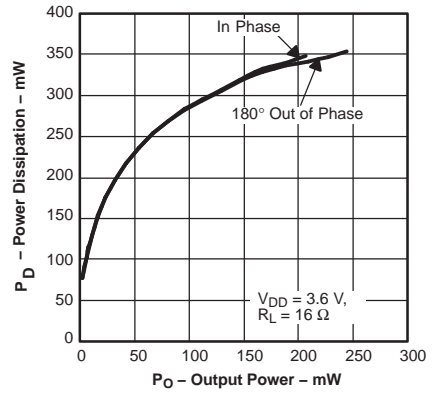


Figure 39.

**POWER DISSIPATION VS OUTPUT POWER**

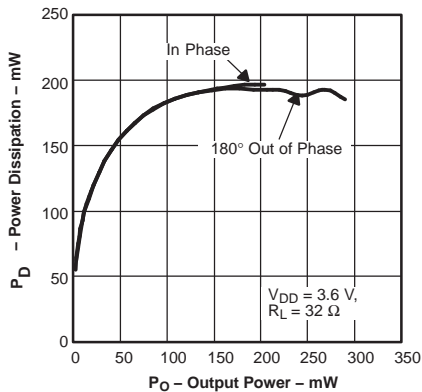


Figure 40.

**POWER DISSIPATION VS OUTPUT POWER**

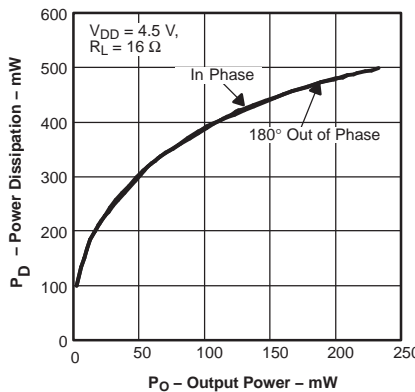


Figure 41.

**POWER DISSIPATION VS OUTPUT POWER**

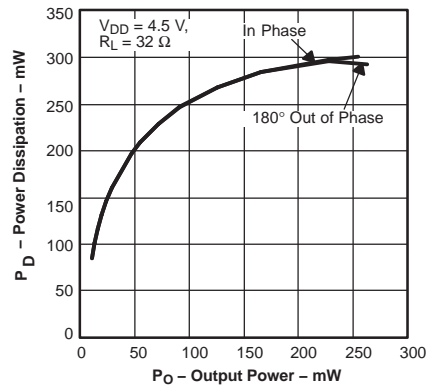


Figure 42.

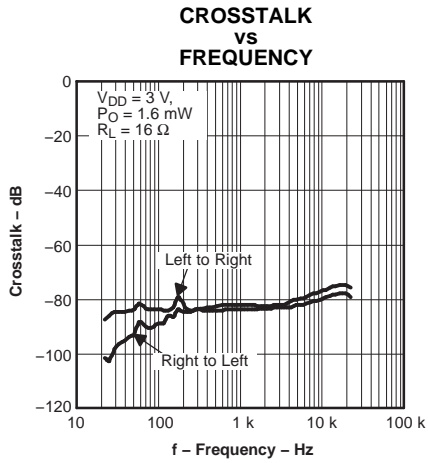


Figure 43.

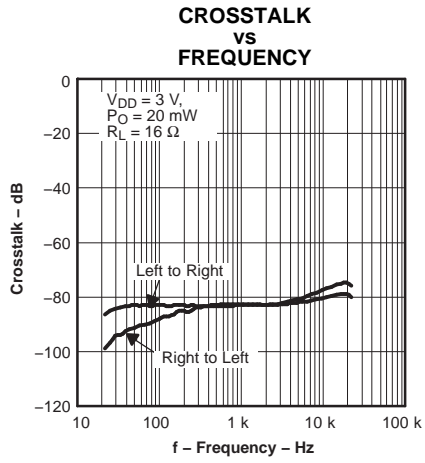


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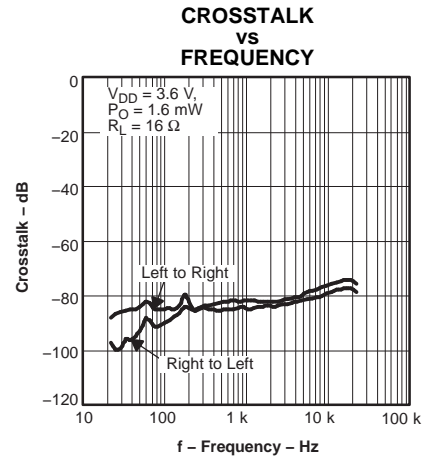


Figure 45.

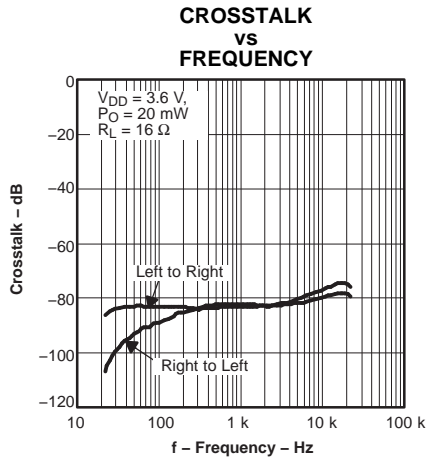


Figure 46.

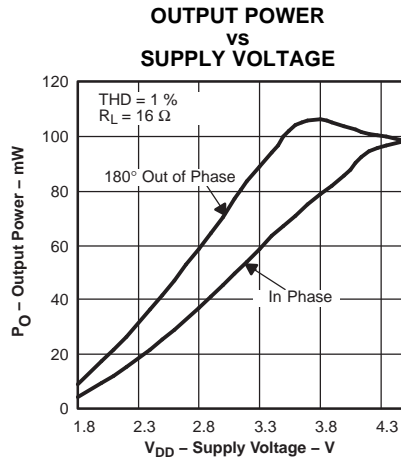


Figure 47.

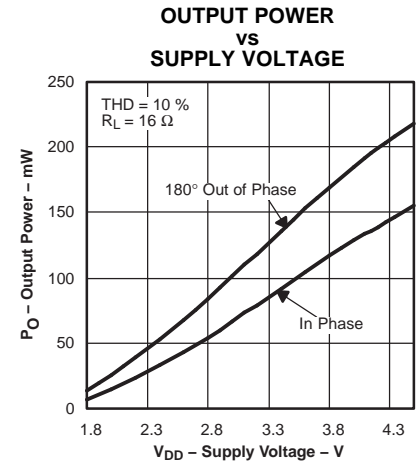


Figure 48.

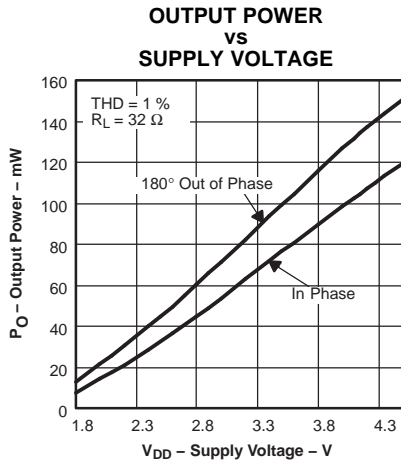


Figure 49.

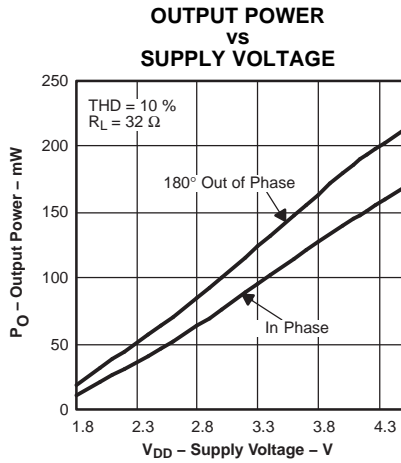


Figure 50.

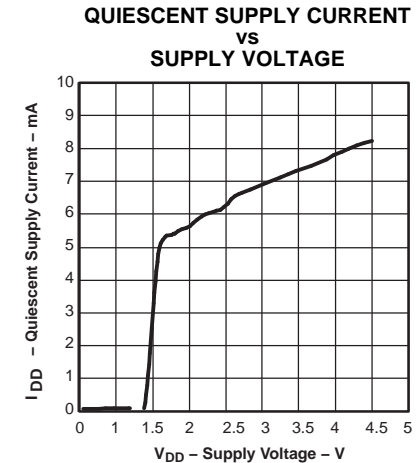


Figure 51.

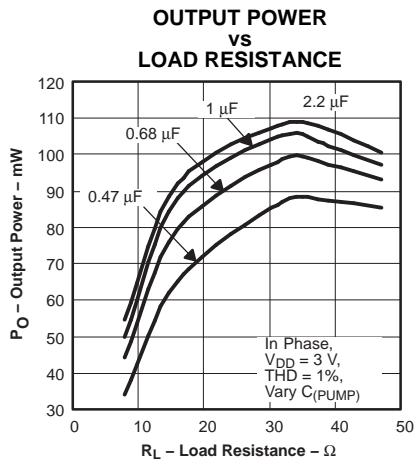


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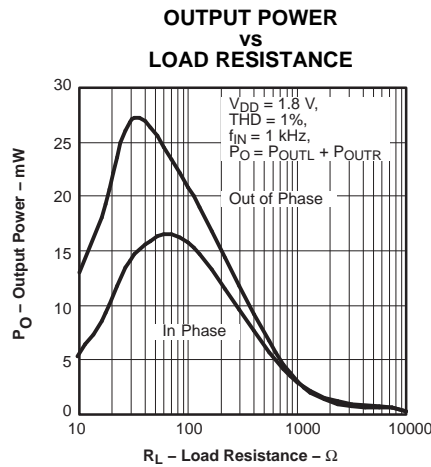


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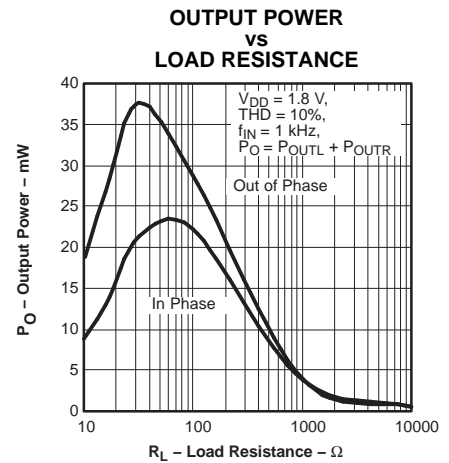


Figure 54.

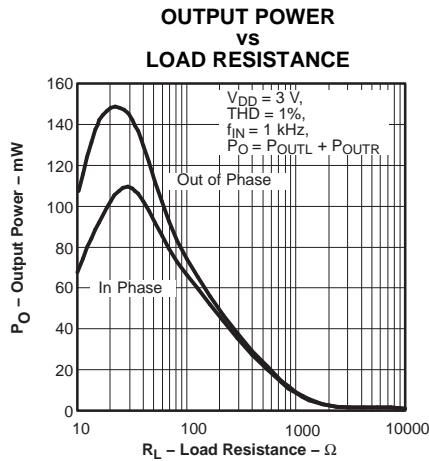


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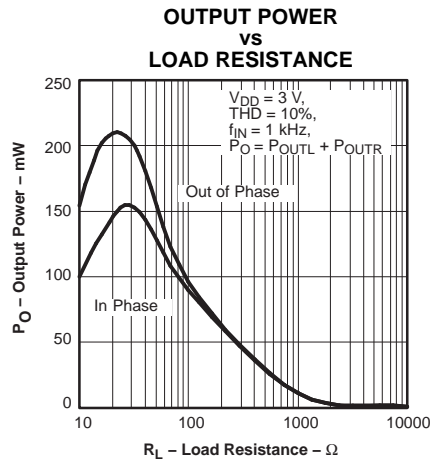


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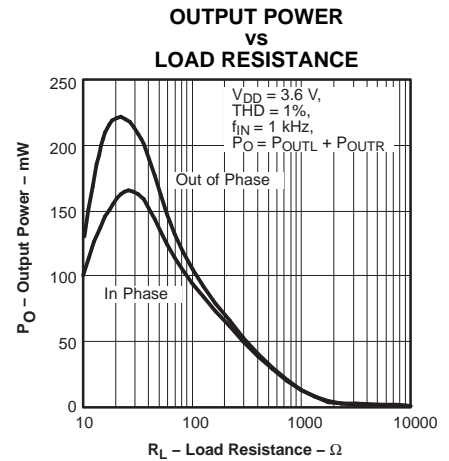


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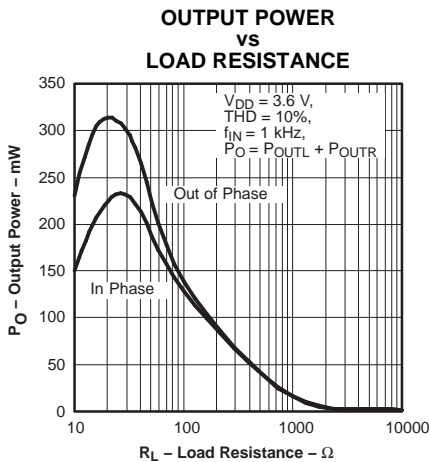


Figure 58.

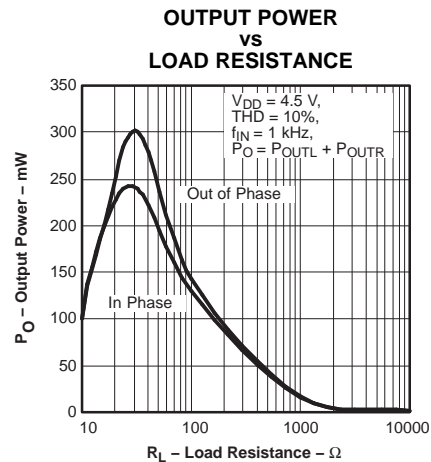


Figure 59.

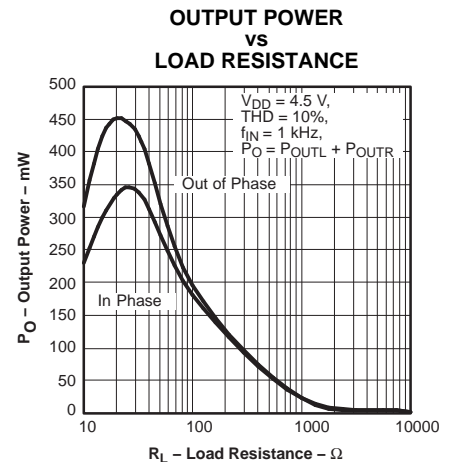


Figure 60.

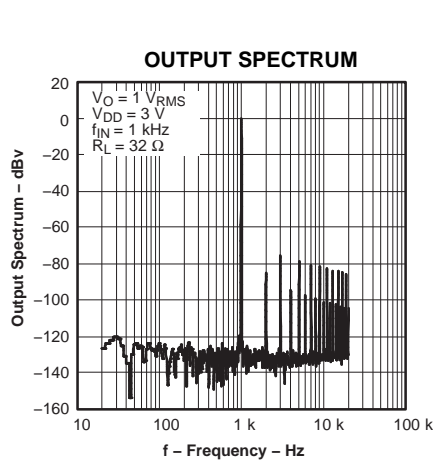


Figure 61.

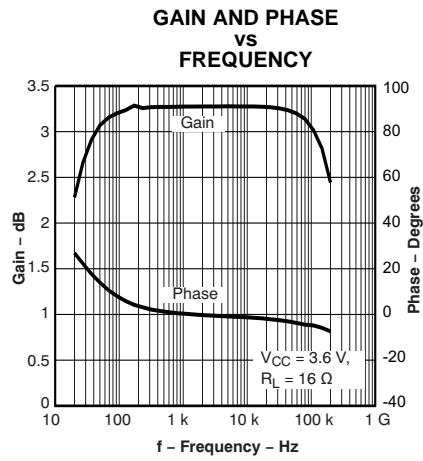


Figure 62.

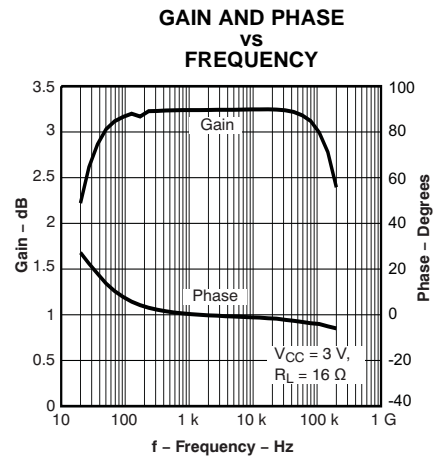


Figure 63.

## APPLICATION INFORMATION

### Headphone Amplifiers

Single-supply headphone amplifiers typically require dc-blocking capacitors. The capacitors are required because most headphone amplifiers have a dc bias on the outputs pin. If the dc bias is not removed, the output signal is severely clipped, and large amounts of dc current rush through the headphones, potentially damaging them. The top drawing in [Figure 64](#) illustrates the conventional headphone amplifier connection to the headphone jack and output signal.

DC blocking capacitors are often large in value. The headphone speakers (typical resistive values of 16 Ω or 32 Ω) combine with the dc blocking capacitors to form a high-pass filter. [Equation 1](#) shows the relationship between the load impedance ( $R_L$ ), the capacitor ( $C_O$ ), and the cutoff frequency ( $f_C$ ).

$$f_C = \frac{1}{2\pi R_L C_O} \quad (1)$$

$C_O$  can be determined using [Equation 2](#), where the load impedance and the cutoff frequency are known.

$$C_O = \frac{1}{2\pi R_L f_C} \quad (2)$$

If  $f_C$  is low, the capacitor must then have a large value because the load resistance is small. Large capacitance values require large package sizes. Large package sizes consume PCB area, stand high above the PCB, increase cost of assembly, and can reduce the fidelity of the audio output signal.

Two different headphone amplifier applications are available that allow for the removal of the output dc blocking capacitors. The Capless amplifier architecture is implemented in the same manner as the conventional amplifier with the exception of the headphone jack shield pin. This amplifier provides a reference voltage, which is connected to the headphone jack shield pin. This is the voltage on which the audio output signals are centered. This voltage reference is half of the amplifier power supply to allow symmetrical swing of the output voltages. Do not connect the shield to any GND reference or large currents will result. The scenario can happen if, for example, an accessory other than a floating GND headphone is plugged into the headphone connector. See the second block diagram and waveform in [Figure 64](#).

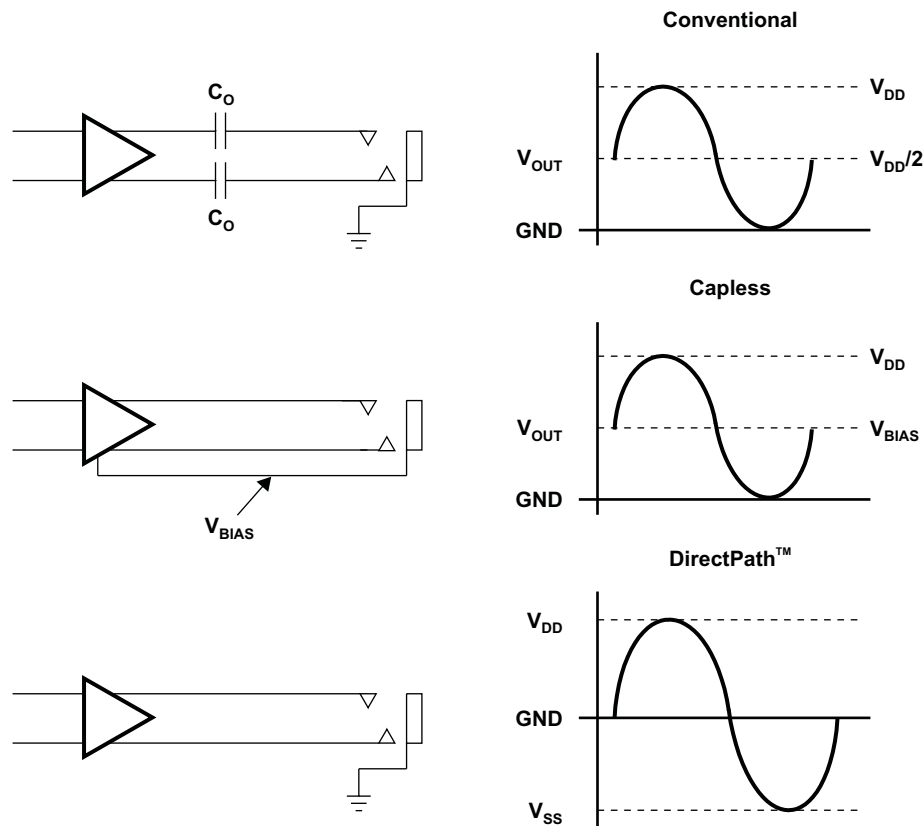


Figure 64. Amplifier Applications

The DirectPath™ amplifier architecture operates from a single supply but makes use of an internal charge pump to provide a negative voltage rail. Combining the user provided positive rail and the negative rail generated by the IC, the device operates in what is effectively a split supply mode. The output voltages are now centered at zero volts with the capability to swing to the positive rail or negative rail. The DirectPath™ amplifier requires no output dc blocking capacitors, and does not place any voltage on the sleeve. The bottom block diagram and waveform of Figure 64 illustrate the ground-referenced headphone architecture. This is the architecture of the TPA4411.

### Input-Blocking Capacitors

DC input-blocking capacitors are required to be added in series with the audio signal into the input pins of the TPA4411 and TPA4411M. These capacitors block the DC portion of the audio source and allow the TPA4411 and TPA4411M inputs to be properly biased to provide maximum performance.

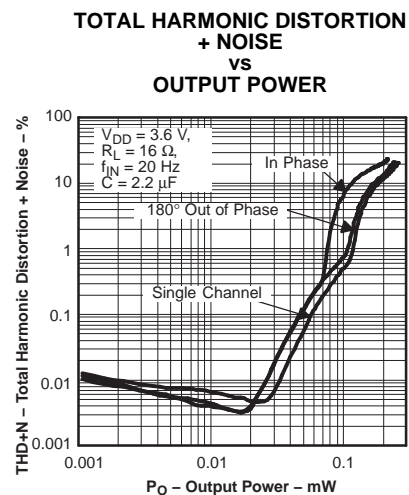
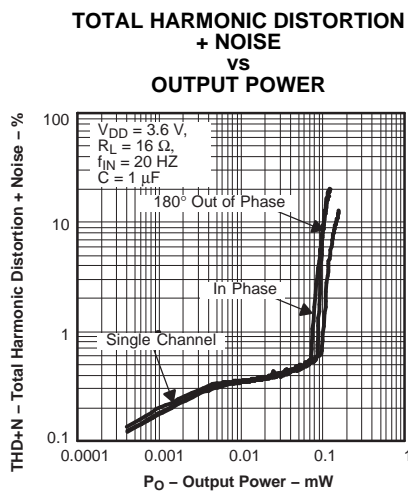
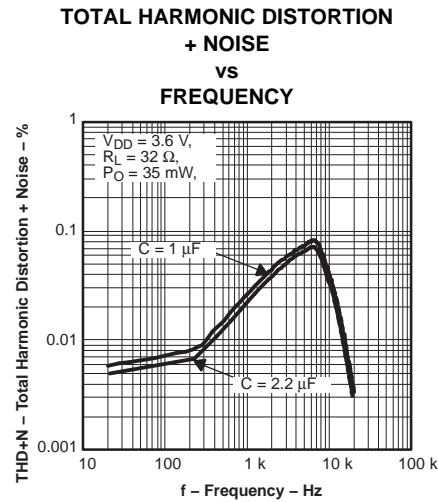
These capacitors form a high-pass filter with the input impedance of the TPA4411 and TPA4411M. The cutoff frequency is calculated using Equation 3. For this calculation, the capacitance used is the input-blocking capacitor and the resistance is the input impedance of the TPA4411 or TPA4411M. Because the gains of both the TPA4411 and TPA4411M are fixed, the input impedance remains a constant value. Using the input impedance value from the operating characteristics table, the frequency and/or capacitance can be determined when one of the two values are given.

$$f_{C_{IN}} = \frac{1}{2\pi R_{IN} C_{IN}} \quad \text{or} \quad C_{IN} = \frac{1}{2\pi f_{C_{IN}} R_{IN}} \quad (3)$$



## Charge Pump Flying Capacitor and PVSS Capacitor

The charge pump flying capacitor serves to transfer charge during the generation of the negative supply voltage. The PVSS capacitor must be at least equal to the charge pump capacitor in order to allow maximum charge transfer. Low ESR capacitors are an ideal selection, and a value of 2.2  $\mu\text{F}$  is typical. Capacitor values that are smaller than 2.2  $\mu\text{F}$  can be used, but the maximum output power is reduced and the device may not operate to specifications. Figure 65 through Figure 75 compare the performance of the TPA4411 and TPA4411M with the recommended 2.2- $\mu\text{F}$  capacitors and 1- $\mu\text{F}$  capacitors.



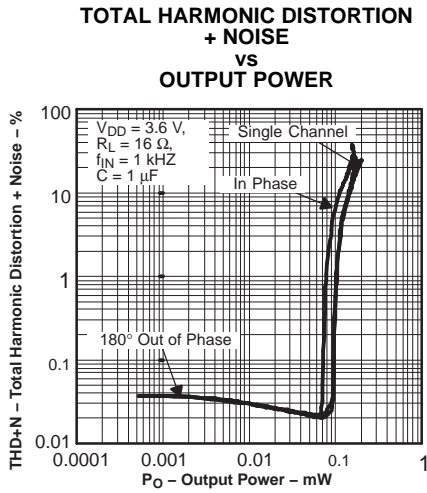


Figure 68.

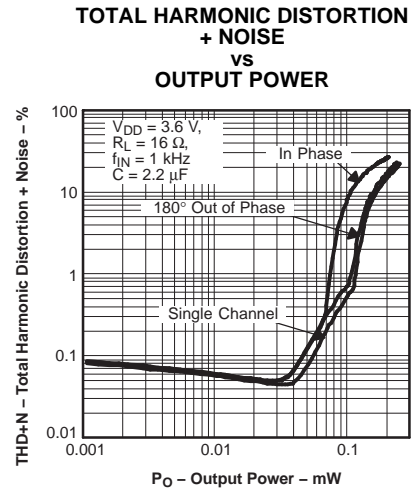


Figure 69.

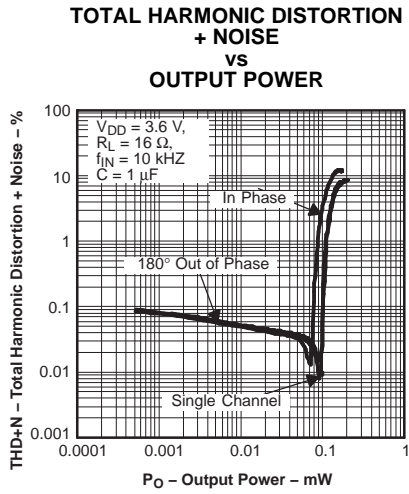


Figure 70.

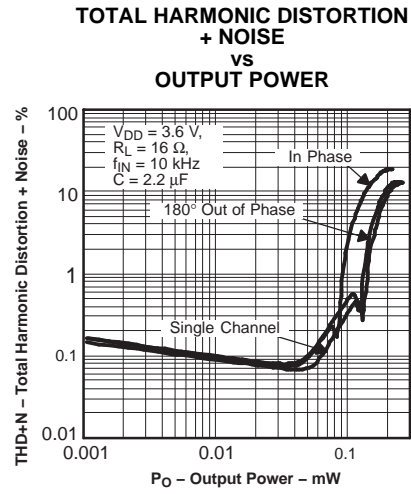


Figure 71.

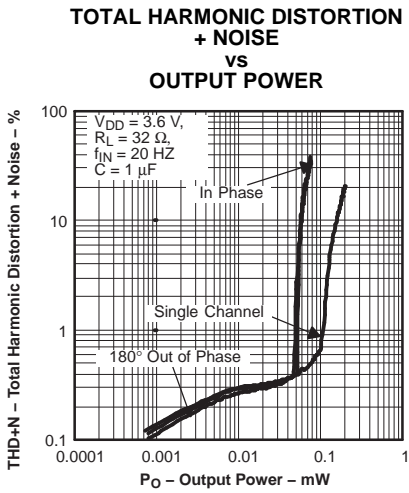


Figure 72.

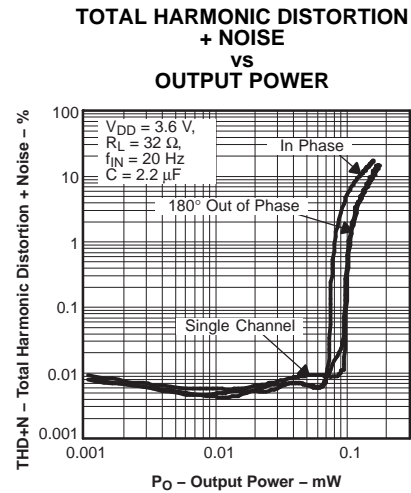


Figure 73.

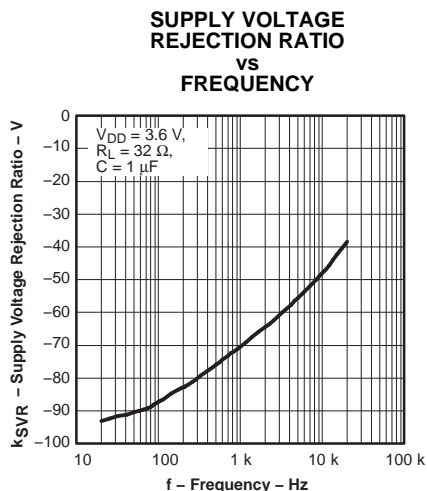


Figure 74.

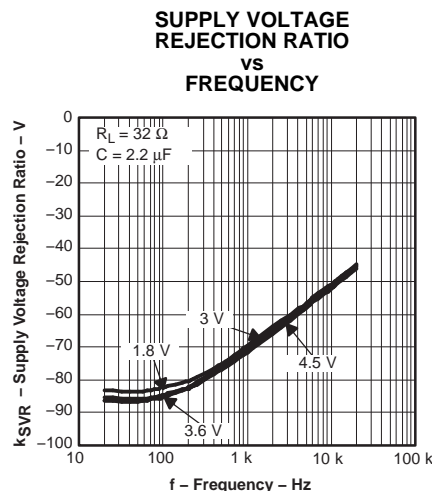


Figure 75.

## Decoupling Capacitors

The TPA4411 and TPA4411M are DirectPath™ headphone amplifiers that require adequate power supply decoupling to ensure that the noise and total harmonic distortion (THD) are low. A good low equivalent-series-resistance (ESR) ceramic capacitor, typically 2.2  $\mu\text{F}$ , placed as close as possible to the device  $V_{\text{DD}}$  lead works best. Placing this decoupling capacitor close to the TPA4411 or TPA4411M is important for the performance of the amplifier. For filtering lower frequency noise signals, a 10- $\mu\text{F}$  or greater capacitor placed near the audio power amplifier would also help, but it is not required in most applications because of the high PSRR of this device.

## Supply Voltage Limiting At 4.5 V

The TPA4411 and TPA4411M have a built-in charge pump which serves to generate a negative rail for the headphone amplifier. Because the headphone amplifier operates from a positive voltage and negative voltage supply, circuitry has been implemented to protect the devices in the amplifier from an overvoltage condition. Once the supply is above 4.5 V, the TPA4411 and TPA4411M can shut down in an overvoltage protection mode to prevent damage to the device. The TPA4411 and TPA4411M resume normal operation once the supply is reduced to 4.5 V or lower.

## Layout Recommendations

### Exposed Pad On TPA4411RTJ and TPA4411MRTJ Package Option

The exposed metal pad on the TPA4411RTJ and TPA4411MRTJ packages must be soldered down to a pad on the PCB in order to maintain reliability. *The pad on the PCB should be allowed to float and not be connected to ground or power.* Connecting this pad to power or ground prevents the device from working properly because it is connected internally to PVSS.

### TPA4411RTJ and TPA441MRTJ PowerPAD Sizes

Both the TPA4411 and TPA4411M are available in a 4 mm  $\times$  4mm QFN. The exposed pad on the bottom of the package is sized differently between the two devices. The TPA4411RTJ PowerPAD is larger than the TPA4411MRTJ PowerPAD. Please see the layout and mechanical drawings at the end of the datasheet for proper sizing.

### SGND and PGND Connections

The SGND and PGND pins of the TPA4411 and TPA4411M must be routed separately back to the decoupling capacitor in order to provide proper device operation. If the SGND and PGND pins are connected directly to each other, the part functions without risk of failure, but the noise and THD performance do not meet the specifications.

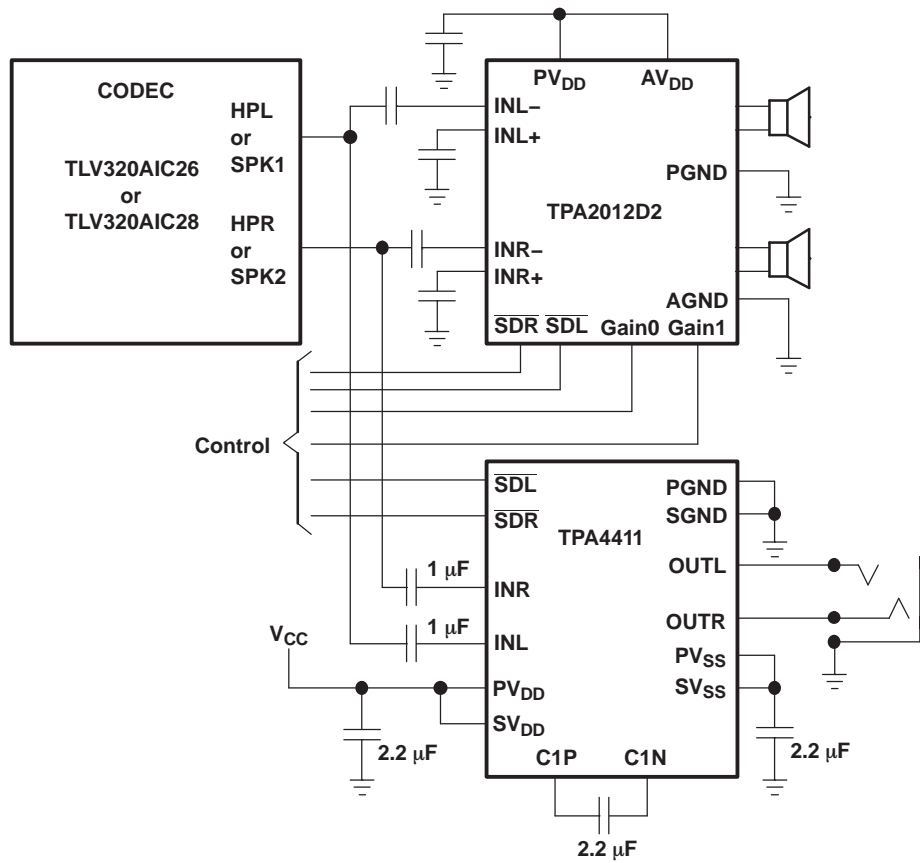
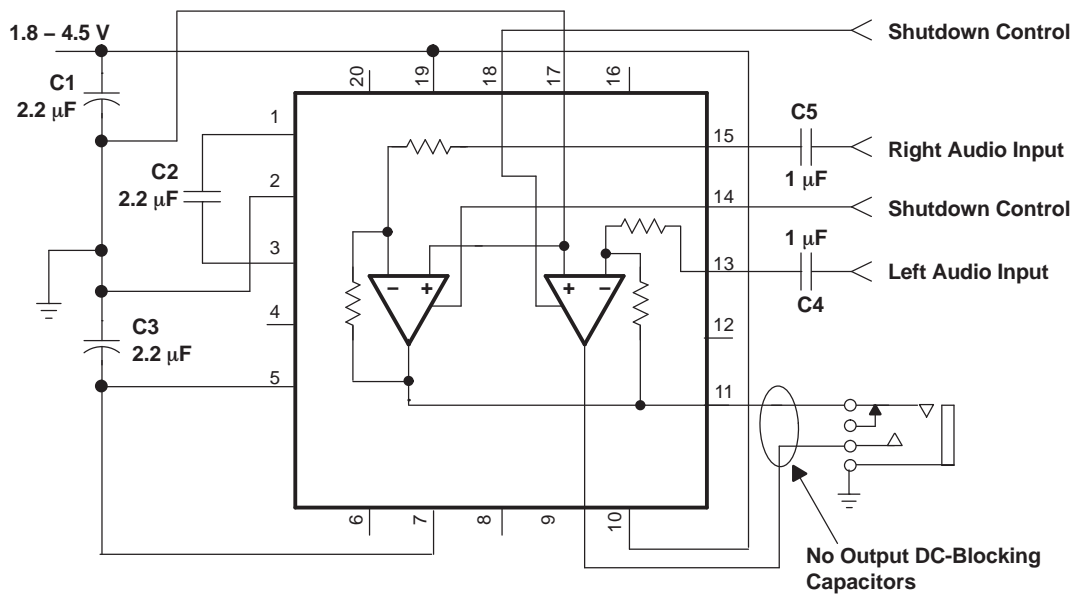


Figure 76. Application Circuit

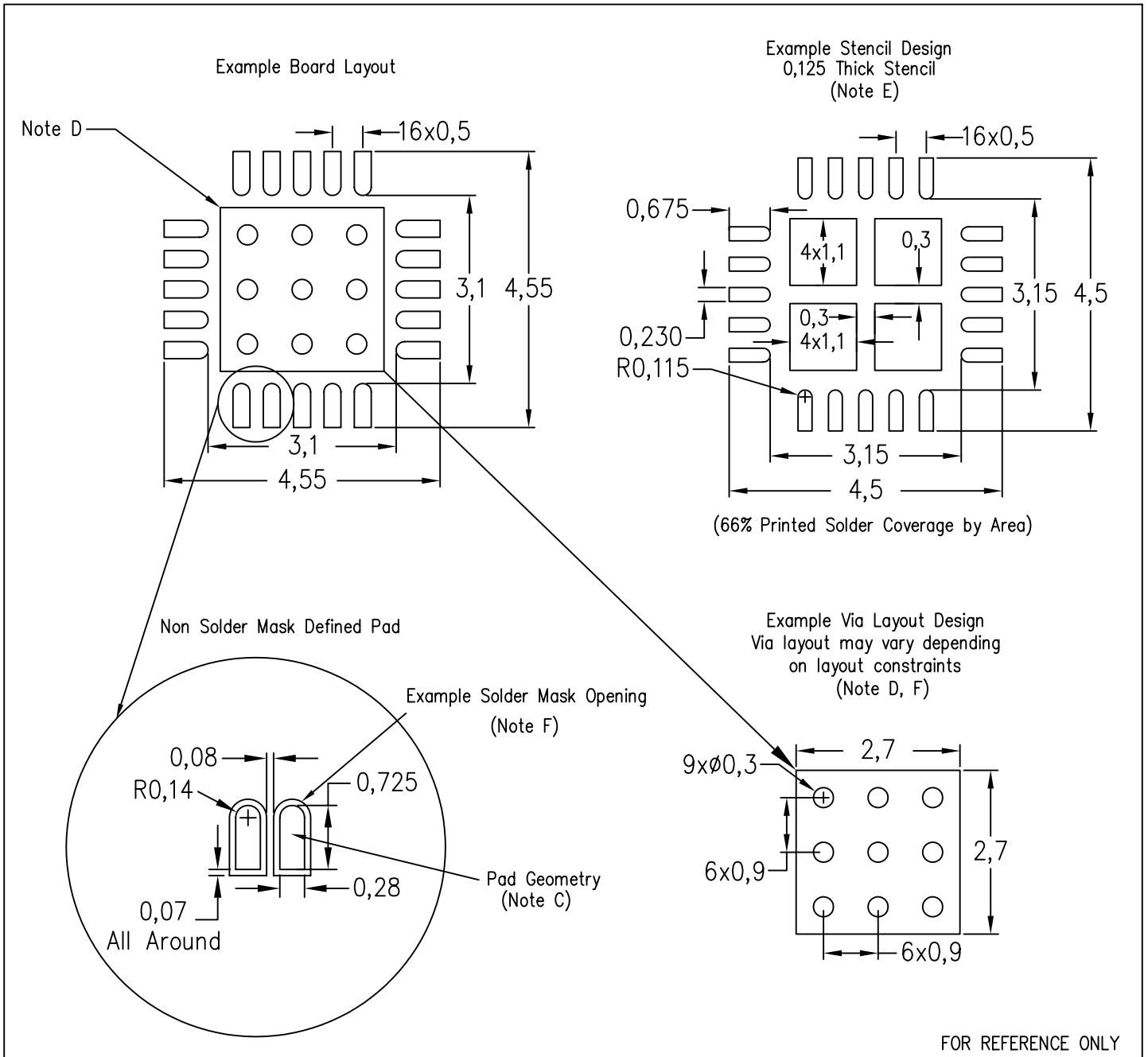


Note: PowerPAD must be soldered down and plane must be floating.

Figure 77. Typical Circuit

TPA4411RTJ

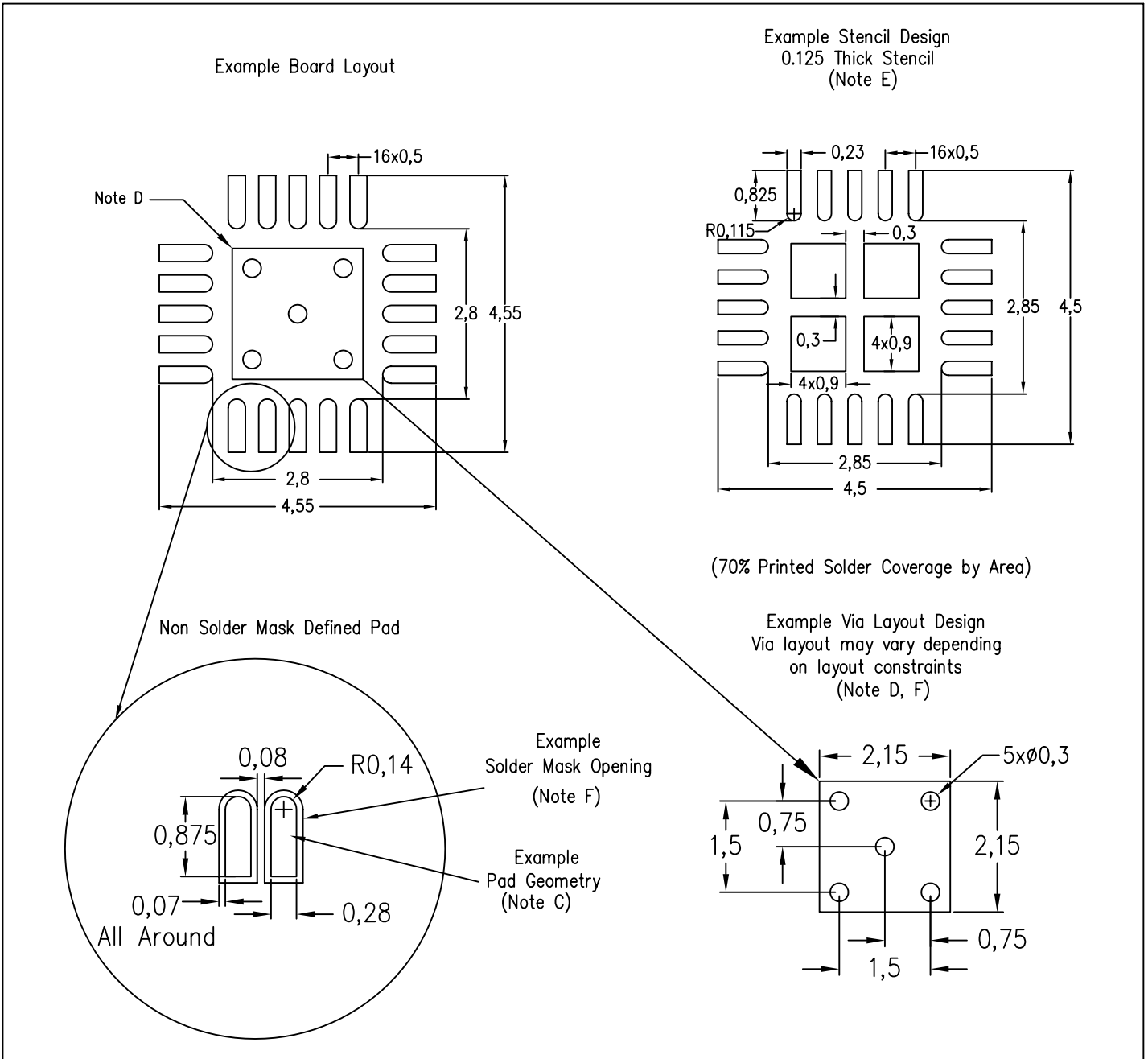
RTJ (S-PQFP-N20)



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-SM-782 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

TPA4411MRTJ

RTJ (S-PQFP-N20)



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-SM-782 is recommended for alternate designs.
  - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPA4411MRTJR	ACTIVE	QFN	RTJ	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	BPB	<a href="#">Samples</a>
TPA4411MRTJT	ACTIVE	QFN	RTJ	20	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	BPB	<a href="#">Samples</a>
TPA4411RTJR	ACTIVE	QFN	RTJ	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	AKQ	<a href="#">Samples</a>
TPA4411RTJT	ACTIVE	QFN	RTJ	20	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	AKQ	<a href="#">Samples</a>
TPA4411YZHR	ACTIVE	DSBGA	YZH	16	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	AKT	<a href="#">Samples</a>
TPA4411YZHT	ACTIVE	DSBGA	YZH	16	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	AKT	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

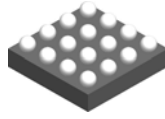
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA4411YZHR	DSBGA	YZH	16	3000	180.0	8.4	2.38	2.4	0.8	4.0	8.0	Q1
TPA4411YZHT	DSBGA	YZH	16	250	180.0	8.4	2.38	2.4	0.8	4.0	8.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPA4411YZHR	DSBGA	YZH	16	3000	182.0	182.0	20.0
TPA4411YZHT	DSBGA	YZH	16	250	182.0	182.0	20.0

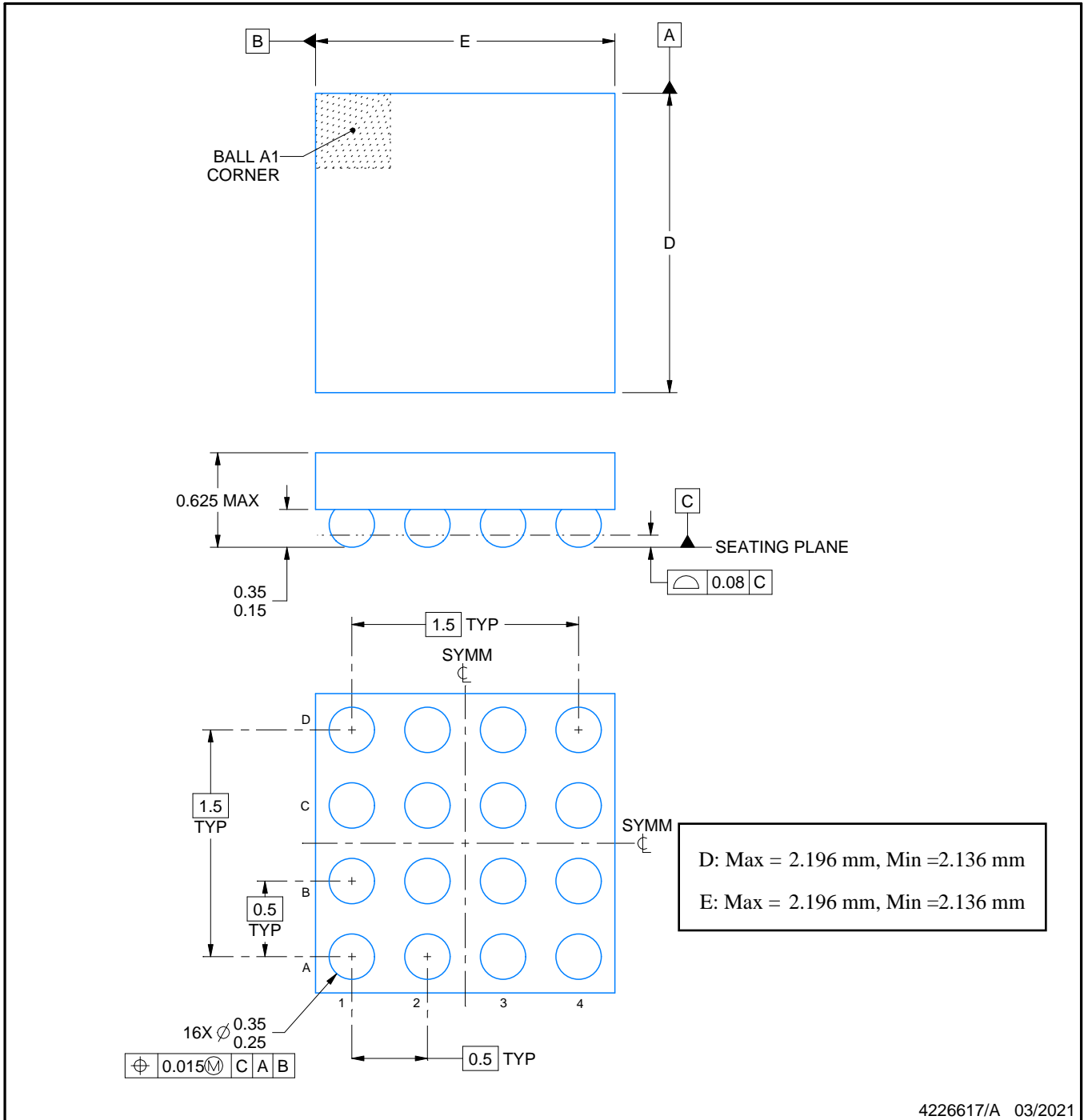
YZH0016



# PACKAGE OUTLINE

## DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



### NOTES:

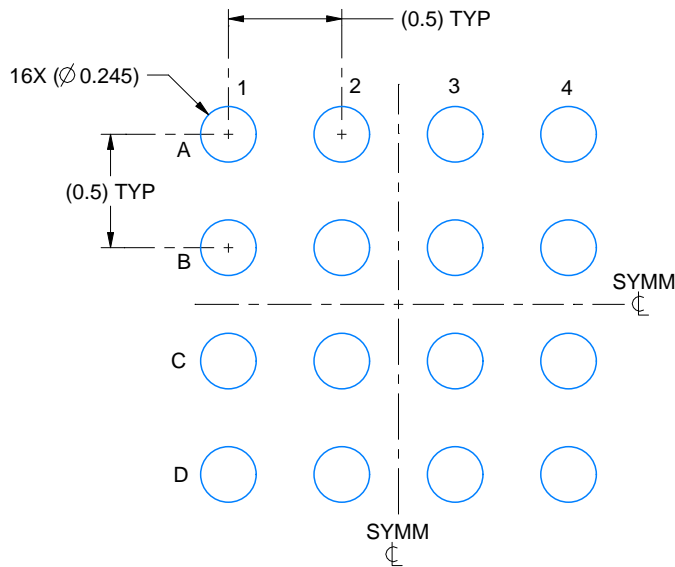
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

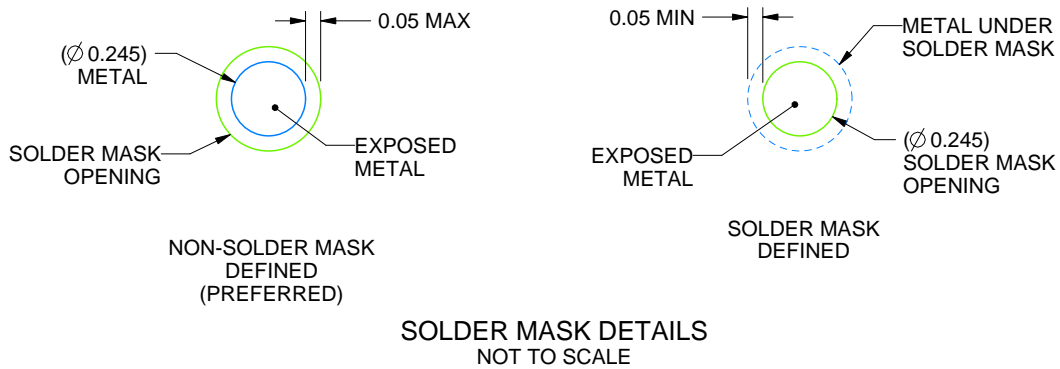
YZH0016

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 30X



SOLDER MASK DETAILS  
NOT TO SCALE

4226617/A 03/2021

NOTES: (continued)

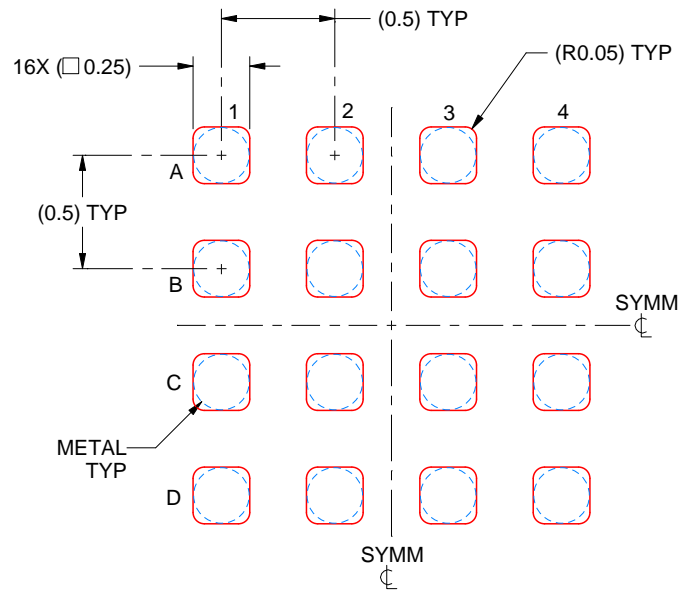
- 3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

# EXAMPLE STENCIL DESIGN

YZH0016

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.075 mm THICK STENCIL  
SCALE: 30X

4226617/A 03/2021

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

## GENERIC PACKAGE VIEW

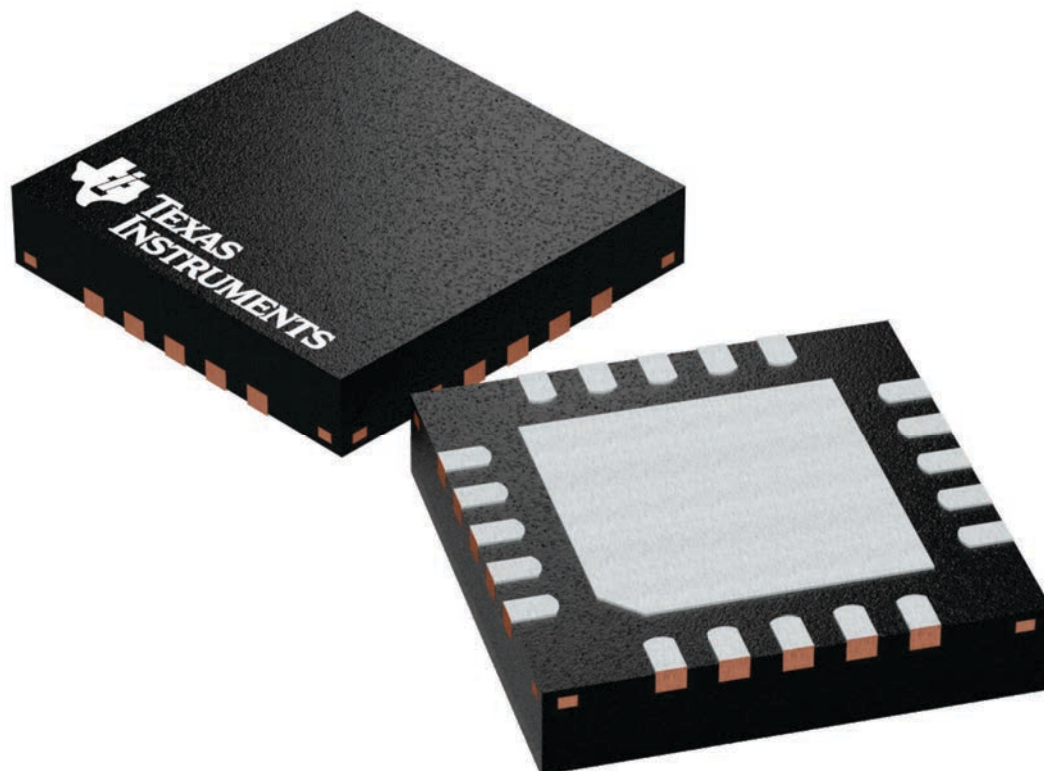
**RTJ 20**

**WQFN - 0.8 mm max height**

4 x 4, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD


This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224842/A

# DATA BOOK PACKAGE OUTLINE

LEADFRAME EXAMPLE
4222370

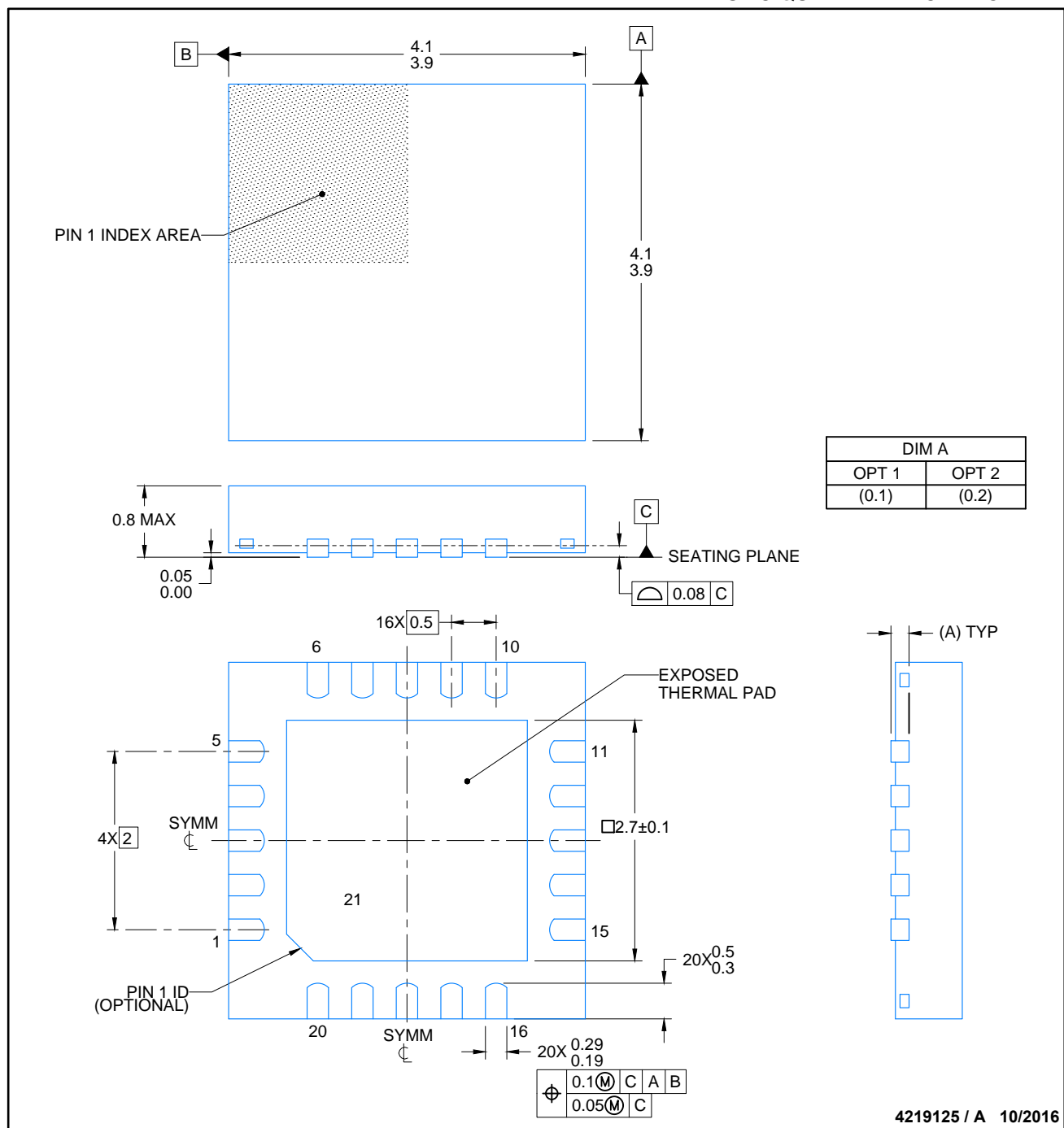
DRAFTSMAN: H. DENG	DATE: 09/12/2016		DIMENSIONS IN MILLIMETERS								
DESIGNER: H. DENG	DATE: 09/12/2016	 <b>TEXAS INSTRUMENTS</b> SEMICONDUCTOR OPERATIONS	CODE IDENTITY NUMBER 01295								
CHECKER: V. PAKU & T. LEQUANG	DATE: 09/12/2016		<b>ePOD, RTJ0020D / WQFN, 20 PIN, 0.5 MM PITCH</b>								
ENGINEER: T. TANG	DATE: 09/12/2016										
APPROVED: E. REY & D. CHIN	DATE: 10/06/2016										
RELEASED: WDM	DATE: 10/24/2016										
TEMPLATE INFO: EDGE# 4218519	DATE: 04/07/2016	<table border="1" style="display: inline-table; border-collapse: collapse;"> <tr> <td style="padding: 2px;">SCALE</td> <td style="padding: 2px;">SIZE</td> </tr> <tr> <td style="text-align: center;">15X</td> <td style="text-align: center;">A</td> </tr> </table>	SCALE	SIZE	15X	A	<table border="1" style="display: inline-table; border-collapse: collapse;"> <tr> <td style="padding: 2px;">REV</td> <td style="padding: 2px;">PAGE</td> </tr> <tr> <td style="text-align: center;">A</td> <td style="text-align: center;">1 OF 5</td> </tr> </table>	REV	PAGE	A	1 OF 5
SCALE	SIZE										
15X	A										
REV	PAGE										
A	1 OF 5										
		<b>4219125</b>									

# RTJ0020D

# PACKAGE OUTLINE

WQFN - 0.8 mm max height

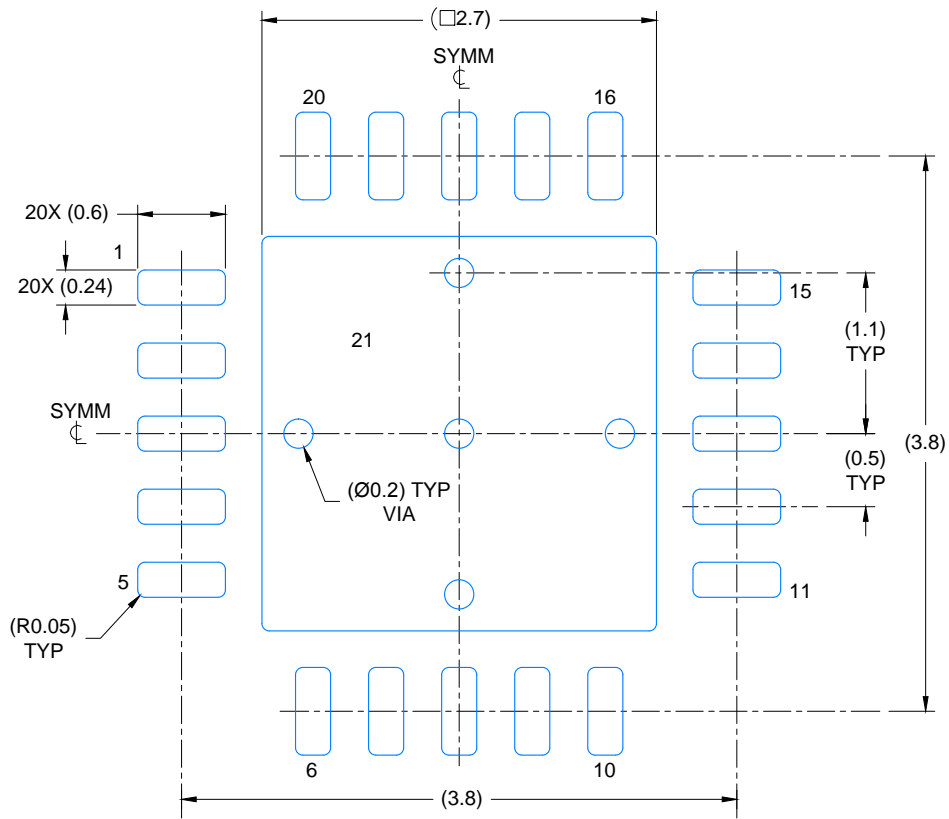
PLASTIC QUAD FLATPACK - NO LEAD



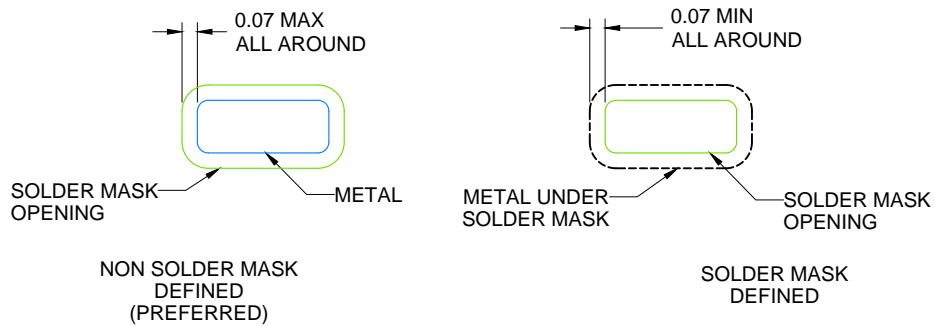
**NOTES:**

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.





LAND PATTERN EXAMPLE  
SCALE: 20X

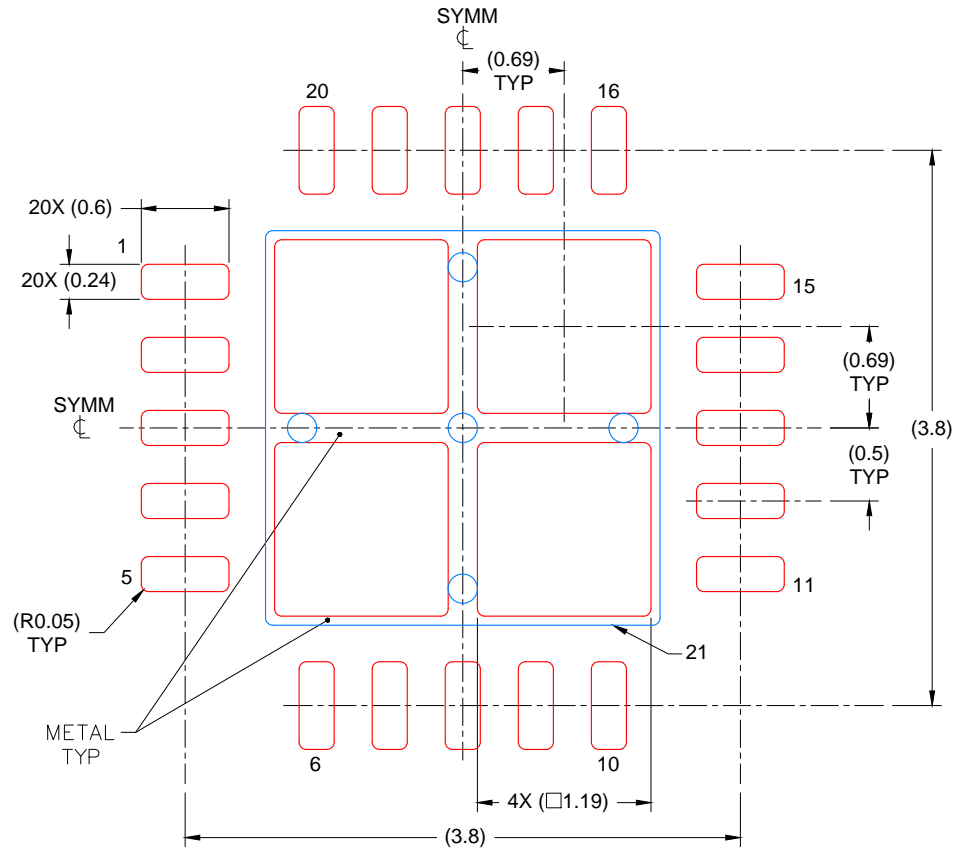


SOLDER MASK DETAILS

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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE  
 BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD  
 78% PRINTED COVERAGE BY AREA  
 SCALE: 20X

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NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations..

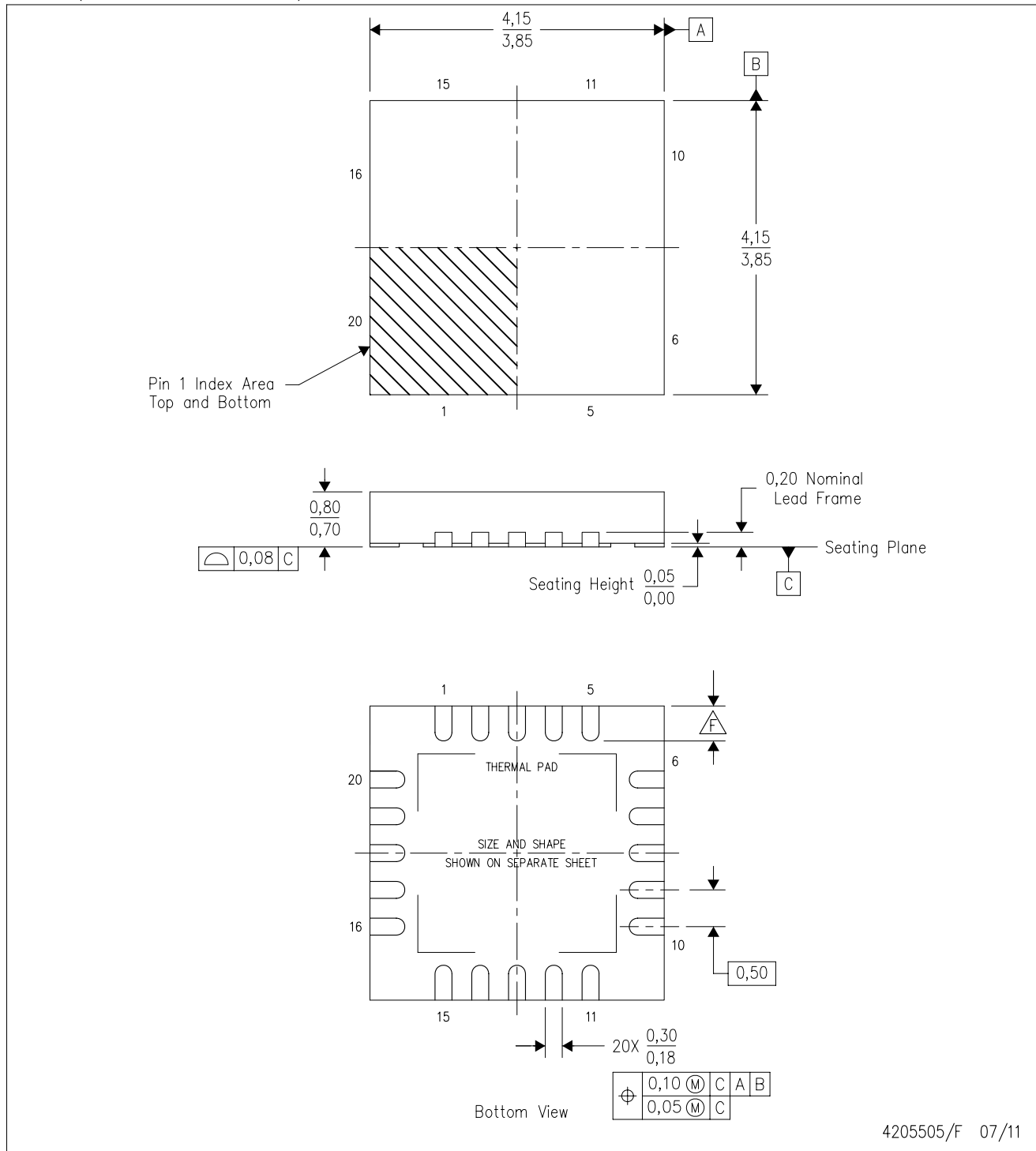
# REVISIONS

REV	DESCRIPTION	ECR	DATE	ENGINEER / DRAFTSMAN
A	RELEASE NEW DRAWING	2160736	10/24/2016	T. TANG / H. DENG

Large empty rectangular area for drawing content.

RTJ (S-PWQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



4205505/F 07/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
  - B. This drawing is subject to change without notice.
  - C. QFN (Quad Flatpack No-Lead) package configuration.
  - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Check thermal pad mechanical drawing in the product datasheet for nominal lead length dimensions.

RTJ (S-PWQFN-N20)

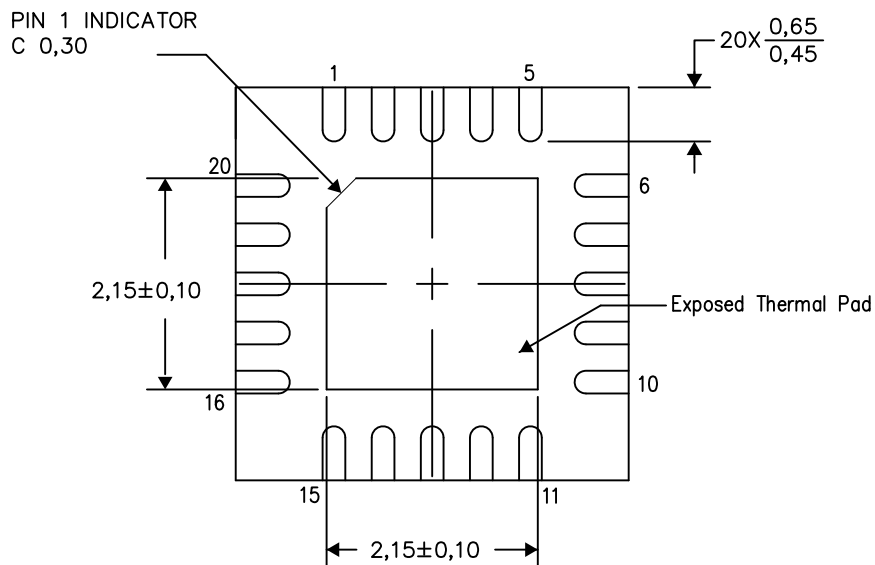
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206256-3/V 05/15

NOTE: All linear dimensions are in millimeters

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